

PROJECT REPORT

ON

"EARTHWORM PROJECT FOR SUSTAINAABLE AGRICULTURE"

2021-22



**PREPARED BY
DEPARTMENT OF BOTANY
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REPORT

A project was undertaken by +3 3rd year students of Department of Botany on "Earthworm project for sustainable Agriculture" under the guidance of Dr. Anjali Kumari Dash, HOD Botany for the academic year 2021-22. 15 numbers of students have been participated in this project work. They have worked for 3 months to complete this project. They prepared vermicompost by using cow dung, decomposing vegetables, food waste and bedding materials with the help of earthworm in a tank by maintaining the temperature of the tank 22^oC to 25^oC with 82-85% moisture content. They have taken two same sized healthy plants of Kalanchoe pinnata, Tagetes patula and Andrographis paniculata for their experiment and applied vermicompost to one plant of each species and kept for observation for about 15 days. After 15 days it was observed that the plants with vermicompost had better growth than the plants without vermicompost.

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02.05.2022
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Abstract

Vermicompost restores microbial population which includes nitrogen fixers, phosphorous solubilizer etc. It provides major and micronutrients to the plants. It also improves soil texture and water holding capacity of the soil.

We 15 students of our botany department started preparing vermicompost by using cow dung, decomposing vegetables, food waste and bedding materials with the help earthworm, in a tank. Temperature of the tank was 22°C - 25°C with 82-85% of moisture content. It took 3 months to convert it in a usable form. Then we took two same sized healthy plant of *Kalanchoe Pinnata*, *Tagetes patula*, *Andrographis paniculata* and then the prepared vermicompost was applied to one plant of each species. Each plant was left for 15 days. Then it was observed that the plants in which the vermicompost was applied had a noticeable growth in shoot and root as well.

INTRODUCTION

The study area is located near the Pattamundai town. Pattamundai is located at 20.57°N 86.57°E & 22 km from the Bay of Bengal in the Utkal Plains, at an elevation of 6 m from sea level. Pattamundai is a flat, low-lying delta region in the Lower Mahanadi River basin. The Brahmani river divides it from the Aul block. The Pattamundai Canal running from Cuttack to Alva Lock (80.5 km) constructed by the East India Company during the mid 19th century, is a major irrigation canal passing through the city. The river Brahmani is passing by the side of this municipality. The soil with high organic matter 5-15 % formed in temperate and cool humid region and low (1-3 %) in soil arid and semi-arid zones. The average rain-fall in the year was recorded 100-170 cm. while temperature between 20°C-38 °C. During winter, temperature was 10°C-25°C

The college was established in the year 1970 at by the collective efforts of the people of the locality who wanted higher education to come to their door steps.

This college is the 2nd largest college of the district upholds the purpose for which it was founded away back in the late sixties. This college is affiliated to Utkal university which is the premier university of Odisha provides the scope to the students to

pursue their dreams and become successful in life .This college offers higher secondary and undergraduate course in Science, Commerce and Arts. As per the National assessment and accreditation council it holds 'B' grade.

This college has excellent infrastructure, security and facilities. College provide us sports , cultural activities and everything .This college is known for its educational facilities like smart class rooms ,seminar hall ,advance lab , library etc.

In this local area, farmers are using chemical Fertilizer which is affecting useful organism and decreasing soil texture and overall soil quality of field. So we 15 students of our department decide to make a project on vermicompost under the guidance of Dr. Anjali Kumari Dash (HOD of Botany department) and to promote bio fertilizer in local areas for both commercial and environmental benefits. Apart from this in our college canteen and hostel vegetable and food wastes are available. Cow dung is easily available in local areas and all other requirements are easily available so it brings our attraction towards this project.

The vermicompost is a word which is used for the final product (humus-like material) of composting procedure of organic waste materials by earthworms. Many organic wastes have been converted into worm manure (vermicompost) by different

species of earthworms which include cow manure, leaves, paper waste, sheep-goat manure, rice waste, vegetable waste. Vermicomposting process employing earthworms is increasingly being used for conversion of both municipal and industrial wastes to vermicast with reduced metals content. Vermicompost is described as a perfect soil amendment and more eco-friendly as compared to chemical fertilizers.

Compositing is one of the feasible means for converting biodegradable solid wastes into beneficial organic soil amendments for supporting environment friendly agricultural production system. Many beneficial organisms and microorganisms act as chemical decomposer in the process of formation of stable organic end product during compositing. Among them, decomposers like earthworm play significant role in stimulating the process of compositing. It enhances the nutrient value while fastening the process of stable organic end-product formation. This process of involvement of earthworms in preparing enriched compost is called vermicomposting. It is one of the simplest methods to recycle agricultural wastes and to produce quality compost. Earthworm acts physically an aerator, crusher, and mixer, chemically a degrader and a biological stimulator in the process of decomposition. Earthworms consume biomass and excrete it in

a digest form called as worms cast or worm manure .worm casts are popularly called as black gold .They are rich in essential plant nutrients ,plant growth promoting substances ,beneficial soil micro flora and having properties of inhibiting pathogenic microbes . As a results , the organic end products produced by the use of earthworms i.e vermicompost also inherits most of the beneficial properties of black gold .Vermicompost acts as an organic soil amendment improves three dimensional soil health i.e physical ,chemical and biological properties. The earthworm's underground burrows modify soil hydro-thermal and aeration regimes by making the soil more porous thus allowing free movement of air infiltration of water into deeper soil layers for better profile moisture recharge and root water uptake processes .Vermicompost is becoming popular as one the major component of the organic farming system because of its high nutritive value in addition to an important organic soil amendment.

Vermicompost contains earthworm cocoons and increases the population and activity of earthworm in the soil .It is free form pathogens, toxic element, weed seed etc. It minimizes the incidence of pests and diseases .It enhances the decomposition of organic matter in the soil. It contains valuable

vitamins, enzymes, and hormones like auxin, gibberellins, etc. It does not have foul odour unlike manures and decaying organic wastes.

General waste management strategies for organic residues ,such as composting and vermicomposting have been implemented in some developed and developing countries to solve the problem of organic wastes .

Vermicomposting can produce high quality fertilizers which are better as compared to other commercial fertilizers in the market so every farmers need to use vermicompost instead of other chemical fertilizer.

It can be made into a livelihood program and become a source of extra income through selling the vermicompost and also the vermi worms. its use can reduce the economic cost and leads to organic products which fetches higher price in the market .

REVIEW OF LITERATURE

1. Michigan biology teacher Mary Arlene Appelhof arrived at idea of home vermicomposting .In 1972 she realized she wanted to continue composting in winter month despite living in a Northern climate. Her book 'Worms Eat My Garbage' is still held as seminal reading in the field of vermicomposting.
2. Sultan Ahmed Ismail (born on 9 Oct 1951) is an Indian soil biologist and ecologist .His work has centered on technique for regulating biodegradable wastes into fertilizer using local varieties of earthworm and soil bioremediation.
3. Choudhary and Suresh Kumar (2013)showed that application of vermicompost can increase the production of potential of cow pea (*Vigna unguiculata*)in acid soil by improving water retention at field capacity ,permanent wilting point ,bulk density ,and availability of nitrogen ,phosphorous, and potassium there by increasing growth and yield attributes of cow pea.
4. Rekha et al. (2018)recorded that *C. annum* treated with 50% vermicompost showed significant growth than the plant growth enhances viz. Gibberllic acid and indole

acetic acid treated plants. Significant improvement in all the parameters like length of shoots, length of internodes, number of leaves and number of branches was observed in plants at the end of 3rd, 4th, and 5th weeks of treatment. The findings clearly indicate that vermicompost can be exploited as a potential biofertilizer.

5. Manivannan et al. (2009) found that application of vermicompost @5 tonnes/ha gave significantly higher result than the application of inorganic fertilizers @20:80:40 kg ha⁻¹ in French bean (*Phaseolus vulgaris*) in terms of growth, yield (1.6 times) and quality (protein, 1.05 times) and sugar (1.01 times) content in seed of bean. Vermicompost application also improve the physical, chemical and biological properties of clay loam and sandy loam soils of Sivapuri, Chidambaram, Tamilnadu .
6. Rajkhowa and his coworker (2017) reported that integrated use 50% RDF+ VC 2.5 ha⁻¹ , +lime 4 q ha⁻¹ , under the hilly ecosystem of NE India , resulted in significantly higher yield of green gram (10 q ha⁻¹) and improved the soil organic carbon (2.5%), bacteria and fungi population and available N, P₂O₅ and K₂O compared to the sole application of recommended dose of fertilizer.

Materials and Methodology

Materials:

- Water
- Cow dung
- Soil or sand
- Earth worm
- Kitchen wastages(college hostel)
- Dry leaves from field
- A large concrete bin
- Gunny bags
- Dry straw from paddy fields

Methodology:

1. To prepared compost a concrete tank was used.
2. The size of tank depends upon the availability of raw materials.
3. The collected biomass was placed under concrete tank. Under the sunlight for about 8-12 days.
4. Then cow dung was prepared for quick decomposition.
5. 2-3 inch layer soil or sand was added at the bottom of concrete tank.

6. Then fine bedding was prepared by adding decomposed cow dung and leaves the wastes collected from the hostel kitchen. They are distributed on the sand layer.
7. These materials were added in to the tank up to a depth 0.5-1.0 fit.
8. After adding the all bio wastage earthworm species were released over the mixture and the compost was covered with dry straw and gunny bags.
9. Water was sprinkled to maintain moisture.
The tank to prevent the entry of ants, lizards, mouse, snakes etc.
10. The compost was protected from rainwater and direct sunlight.
11. The compost was checked frequently to avoid from over heating and proper moisture and temperature was maintained.
12. We taken the 3 species of plant *Kalanchoe Pinnata*, *Tagetes patula* and *Andrographis paniculata*
13. Two plants from each three species was planted, one is with vermicompost and another was without vermicompost.

14. The growth of plants was checked frequently.

Five phages of vermicomposting

1. Collection of waste material.
2. Pre – digestion.
3. Earth worm pit preparation and compositing
4. Harvesting of vermicompost and Earthworm.
5. Packing and storing of vermicompost.

We used some precautions in the process of making vermicompost .

1. The collected waste materials was processed for shredding, mechanical separation, of the metal, glass, and ceramics and it should be stored in proper places.
2. Pre-digestion of organic waste was done at least 20-25 days by heaping the material along with cow dung slurry and regular watering. This process partially digests the material and fit for earthworm consumption. Addition of higher quantities of acid rich substances such as citrus wastes was avoided.

3. The vermicompost heap was not overloaded, in order to avoid high temperature that adversely affects earthworm's population.
4. Organic materials free from stones, glass pipes, plastics, ceramic tube etc. was used.
5. Temperature was maintained at 30^C by upturning and staking and regular sprinkling of water.
6. Moisture was maintained at about 60% by proper drainage and aeration and by sprinkling of water.
7. The pit should be a bit inclined towards the hole at the bottom of the pit or tube to drain out the excess water. Make sure to have a drainage channel around the heap to avoid stagnation of water.
8. The compost material was turned upside down giving some days gap without disturbing the basal layer.
9. The organic materials were protected from pests and diseases.
10. The earthworms were protected from predators like ants, birds and lizards.
11. A thatched roof was provided to protect the vermicomposting unit from direct sunlight and rain.

RESULT and DISCUSSION:

1. After the 24 days, around 4000-5000 new worms were generated and the entire raw materials was turned into the vermicompost.
2. When this vermicompost was applied to plants, it promoted the growth of stem and root .
3. The plant to which vermicompost was applied was healthier than the other one.
4. It helps to increase the soil texture and overall soil quality.
5. When vermicompost was applied to one plant of each species, then the growth in stem length was observed.
6. The observation is shown below in the table:

SL NO.	Name of the plants	Without vermicompost	With vermicompost
1	<i>Kalanchoe pinnata</i>	16 cm.	19.5 cm.
2	<i>Tagetes patula</i>	18 cm.	24.2 cm.
3	<i>Andrographis paniculata</i>	11 cm.	14 cm.

On the basis of experiment , We concluded that vermicompost increases the fertility and water holding capacity of the soil.

which helps in better plant growth , germination and crop yield.

It is an environment friendly way of reducing wastes , producing fertilizers and maintaining the balance of ecological environment .Farmers can take up vermicompost production which is a good source of macro and micro nutrients ,also several enzymes and growth regulators ,above all it will also maintain soil organic matter .

RECOMMENDATION

Vermiculture is a way of composting using earthworms to speed up the process. We in the group have engaged ourselves in our unique way of innovative vermiculture and vermicomposting activity for almost 3 months .From that span of time , we recommend that , vermicomposting can produce high quality fertilizers which are better compared to other commercial fertilizers in the market so every farmers need to use vermicompost instead of harmful chemical fertilizers . It can be made into a livelihood program and become a source of extra income through selling the vermicast and also the vermiworms . It's use can reduce the economic cost and leads to organic products which fetches higher price in the market.



PROJECT ON "EARTHWORM PROJECT FOR SUSTAINABLE AGRICULTURE"

DEPARTMENT OF BOTANY

PATTAMUNDAI COLLEGE, PATTAMUNDAI, KENDRAPARA

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PROJECT REPORT ON
SOCIO-ECONOMIC CONDITION OF WOMEN
CONSTRUCTION WORKERS IN KENDRAPARA DISTRICT,
ODISHA

PREPARED BY
DEPARTMENT OF ECONOMICS

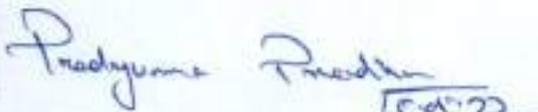


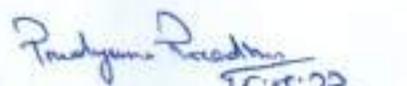
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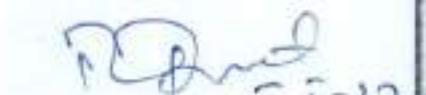
SESSION-2021-22

REPORT

A project on “**Socio-economic condition of women construction workers in Kendrapara district, Odisha**” was undertaken by student of Economics department during the month of March in 2022. 12 no of students participated in the project work. The study has relied upon both primary and secondary data. Primary data were collected randomly from 50 women workers in Kendrapara District. To collect information about the socio-economic condition, problems at workplace and health hazards of the workers, a well-structured schedule was used. The workers are directly met from their workplace mostly during lunch break and observed their working condition. Secondary data were obtained from various sources such as ILO, Economic Review, government reports, journals, and books. Simple percentage analysis was used to interpret the data. The project work was supervised by Mr. Pradyumna Pradhan, Lecturer in Economics. After completion of the project students presented their report before the external and internal examiner.


Signature of Supervisor
15.05.22


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Socio-economic condition of women construction workers in Kendrapara district, Odisha

Abstract

Today, economic independence is the prime basis for improving the status of women in India. It is highly emphasized that women work participation is crucial in enhancing social and economic status as well as improving their assertive roles in the household decision making. In construction activities, health is the important determinant of employment, and it is the deteriorating factors consider to workers especially the women, they are simultaneously engaging in economic and non-economic activities. This study is an attempt to understand the socio-economic condition of women construction workers and a special emphasis has given to identify the work related problems of women in Kendrapara district.

The study largely relays on field data which were collected from 50 respondents in Kendrapara district. A sample size of 50 women respondents were selected from the district by employing simple random sampling method. The respondents were interviewed with a well-structured schedule. Simple percentage and regression analysis was used to interpret the data.

As far as the problems faced by the workers are concerned, 100 percent of the workers are dealing with health problems and 82 percent of the workers faces financial problem. About 30 percent of the workers are facing other problems such as sanitary facility, drinking water facility, wage problems etc. The main health problems faced by the workers are muscle pain, allergy, cough, asthma problem, etc. About 8 percent of the workers are suffering from all of these problems. The nature of hospital preferred by the construction workers is mainly government hospitals. About 86 percent of the women workers opined that their status in the society has been improved by doing construction work.

Introduction

India is the second largest populated country in the world where the construction labour force is estimated at 30 million people; about half are women . The employment of women in the construction work falls under the service sector which is of unorganized category. In this field, both male and female workers are engaged. Women account for half of the total construction labour workforce. Women workers are most exclusively unskilled, casual and of manual labourers. They are mainly engaged in carrying bricks, cement, sand and water and also for digging earth, mixing cement and breaking stones. The construction sector is providing employment to 7% of total world employment .

According to the government of India report, the construction industry employs about 31 million people and creates assets worth over ₹ . 200,000 million in every year . In India, it is the largest employer of unorganized labour next to agricultural sector. About 16% of the India's working population largely relies on construction industry for earning livelihood and the Indian construction industry providing employment to about 31 million people and creates assets worth over ₹ 200,000 million in every year . Nowadays the construction industry in India is facing the problem of shortage of labour. The number of skilled labourers in the construction sector has gradually declined from 15.34% in 1995 to 10.57% in 2005 at the same time the proportions of unskilled workers have gone up from 73.08% in 1995 to 82.45% in 2005. The construction labourers are seems most vulnerable segments of the unorganized sector as there is no adequate job opportunity and income for them .In Odisha, the structural transformation of women's activity has indeed taken place in the state with primary sector losing its importance and tertiary sector taking up its place . The peculiarity of women employment in Odisha is their high proportion in the service sector.

Statement of the problem

Odisha has made exemplary progress on labour welfare front but the occupational statuses of the women working in the unorganized sector are very weak. The women construction worker faces different socio- economic problems and also many work-related health problems. Women workers are mostly unskilled casual manual labourer. They are employed in construction sites

for carrying bricks, cement, sand, water, digging earth, mixing cement and breaking stone. The women are given common chores including transporting of materials around the site. They are rarely found in male-dominated skill trades like carpentry, masonry, plumbing, electrical wiring. There is wage disparity between the male and female workers. Women labourers are paid fewer wages. The risk involved in construction work is very high particularly for women workers who have to climb great heights with the load on their heads. Accidents involving simple injury occur almost every day, while fatal accidents occur occasionally. The major cause of accidents is falling from great heights, falling of heavy objects or collapsing of ladders. Long working hours, lack of proper nourishment, lack of safe drinking water are some of the occupational hazards due to which women are not being able to work for longer periods. Safety risks, health hazards, low wages, poor working conditions are some of the problems faced by the women labourers. They are not aware of their legal rights ensured by the Government. The study intends to analyze the socio-economic condition of women construction workers in Kendrapara district and a special emphasis was given on investigating health hazards and other work related problems.

Objectives of the study

The specific objectives of the study are:

1. To examine the socio – economic profile of the women workers in Kendrapara district.
2. To examine the working condition and occupational health hazards of the women workers.
3. To list out the problems faced by the women workers in the family and society.

Methodology

The study has relied upon both primary and secondary data. Primary data were collected randomly from 50 women workers in Kendrapara District. To collect information about the socio-economic condition, problems at workplace and health hazards of the workers, a well-structured schedule was used. The workers are directly met from their workplace mostly during lunch break and observed their working condition. Secondary data were obtained from various sources such as ILO, Economic Review, government reports, journals, and books. Simple percentage analysis was used to interpret the data.

Results and discussions

Age composition

Workers are classified into five age groups which are depicted in Table 1. Out of 50 samples, the majority workers belong to 45-50 followed by 26 percent are in the 50-55 age group. It is inferred from the table that 11 percent of workers are included in the age group of 40-45. Only 8 percent of workers are belonging to the age group of 50-55 and 4 percent of workers are in the age group of 35-40. From the total sample, none of them belongs to the age group of below 30. It could be clear that the new generation is not interested in working in the construction field. As far as the marital status is concerned, it is revealed that among the 50 samples, 72 percent workers are married and they are living with their husband, 14 percent are the widow and 12 percent are unmarried. Only 2 percent workers are divorced.

Table 1. Distribution of the respondents by age

Age	No of female workers	Percentage
30-35	0	0
35-40	4	8
40-45	11	22
45-50	14	28
50-55	8	16
55-60	13	26
Total	50	100

Educational status

Education is an important factor that is capable of determining the economic as well as social status in everyone's life. In this case, we are looking whether the workers are educated or not. Table 2 shows the education status of the women workers. About 50 percent of the workers having primary education whereas 46 percent are secondary educated and 4 percent of workers are illiterate. The majority of the workers are primary educated. Poor educational status coupled with the absence of bargaining power has resulted in the problem of low levels of wages and income accruing to workers. Lack of education has also meant very poor levels of awareness of rights among the workers.

Table 2. Educational status of the respondents

Education	No of female workers	Percentage
Illiterate	2	4
Primary	25	50
Secondary	23	46
Graduate	0	0
Total	50	100

Monthly income

Construction workers are wage earners and their wage is fixed in nature. The daily wage is given either every Saturday or when the work is completed. Mostly in Kendrapara areas, the wage has been given on Saturdays. Table 3 shows that 48 percent of the respondents have earned an income of 4000-6000 and 24 percent of the workers come under the category of 2000-4000. Only 12 percent of the workers' income is above 10000.

Table 3. Classification of the respondents on the basis of monthly income

Monthly Income	No of female workers	Percentage
2000-4000	12	24
4000-6000	24	48
6000-8000	5	10
8000-10000	3	6
Above 10000	6	12
Total	50	100

Expenditure pattern

The expenditure pattern of the workers and their family is represented in the Table 4. It is inferred from the table that only small percent of workers spent amount between Rs 1000-1500 per month. About 24 percent of the workers spend ₹. 1500-2000 and 26 percent of workers belonging to ₹. 2000-2500. About 40 percent of the workers have come under the category of

above 2500. It is revealed that the propensity to consume is very high.

Table 4. Monthly expenditure of the family

Monthly expenditure	No of female workers	Percentage
1000-1500	5	10
1500-2000	12	24
2000-2500	13	26
2500 and above	20	40
Total	50	100

Membership in SHG

Nowadays, SHG has got more importance, and also many women are joining and actively participate to various activities of SHGs. Table 5 shows the number of workers are engaged SHGs activities. It is found that 52 percent of the workers have membership in the SHG while 48 percent are not a member of SHGs.

Table 5. Classification on the basis of membership in SHG

SHG	No of female workers	Percentage
Yes	26	52
No	24	48
Total	50	100

Seasonal employment

There are many jobs which are seasonal. In this case, availability of construction work construction work seems to be limited in monsoon whereas continues job availability in the summer and winter seasons. Table 6 exhibits the seasonality of construction work. 60 percent of the workers opined that the employment is not seasonal while 40 percent of the workers opined that work is seasonal in nature. It is noted that they are ready to go for other works such as beedi work, stitching, NREGP etc. during the off-season.

Table 6. Seasonality of the work

Employment seasonal	No of female workers	Percentage
Yes	20	40
No	30	60
Total	50	100

Time of work

Table 7. Classification of workers according to their working hours

Time of work	No of female workers	Percentage
Below 8 hours	4	8
8 hours	36	72
Above 8 hours	10	20
Total	50	100

Each work is having a time schedule. Normally, maximum hours of time are regarded as eight hours but in the unorganised sector it has not prevailed. It is possible to categorize the hours of work into three- below eight hours, eight hours and above eight hours. The classification of workers as per their daily hours of work is exhibited in the Table 7. The statutory laws in the organized set up expect the workers to work for 8 hours per day. Construction workers asked to work more than 8 hours. From the Table 7, it clear that 72 percent of the workers are work for 8 hours while 20 percent of the workers belong to the category of overtime (above 8 hours). There are some workers working below 8 hours.

Occupational status

The construction sector consists of a series of work which are collectively called construction work. The works such as carpentry, stone work, roof work, electrical work, tile/bricks/block works and concrete works, etc. Women are employed in construction sites for carrying bricks, cement, sand, water, digging earth, mixing cement and breaking stones. From these categories, the sample respondents are classified into four on the basis of their work.

Table 8. Classification of construction workers by occupation

Type of work	No of female workers	Percentage
Sand	2	4
Stone	9	18
Concrete	20	40
All of the above	19	38
Total	50	100

It is shown in the Table 8 that about 40 percent of the workers are engaged in concrete work, 38 percent of the workers are in carrying stone and 38 percent of the workers do all the work. Lowest percent of workers are engaged in sand work (4 percent). The workers carry 40-80 stone in a day and also the weight of the cement slack is about 50kg. One of the main hindrances for the workers is the distance to the workplace. When the distance of the workplace becomes too far the effort taken by the workers should also become very high. It is implied that the distance between workplace is categorized into four and most of the workers are coming from above 11 kilometres. While the distance between works place of some others is in the category of 1-4 kilometer. 32 percent of the workers are having a distance of 4-8 (16 percent) and 8-11 (16 percent) kilometer. Women workers find it very difficult to travel a long distance and then get into work. Also, it makes very difficult to manage their household activities. To achieve in their targeted place there is a need of the mode of conveyance. About 42 percent of the workers use bus as their conveyance and some prefer both bus and walking (40 percent). Only 18 percent of the workers walk to their construction site. No accommodation facility is given to the workers.

Saving habit

Saving habit is very essential in the life of each person which allocated from income with an expectation to meet future benefit and needs. Here, we look the saving habit of the women workers in a month which is shown in Table 9. That out of 50 samples, 42 percent of the workers have the saving in between the ₹. 500- 1000 whereas 36 percent of the workers save the amount of 0-500 rupees/month. Only 6 percent of the workers save more than 1500. Most of the workers use their salary for family expenditure. So their marginal propensity to consume is very high and marginal propensity to save almost zero.

Table 9. Monthly saving habits of the respondents

Saving	No of female workers	Percentage
Nothing	2	4
0-500	18	36
500-1000	21	42
1000-1500	6	12
Above 1500	3	6
Total	50	100

Debt of the respondents

Each person takes loan for many purposes due to low income and the workers are not able to meet their needs with their limited income. The debt status of women construction workers is shown in Table 11. The debt burden of construction workers shows that about 82 percent of the workers are in debt trap whereas 18 percent of workers have not taken any loan from bank or other financial institutions. The debts are taken for different purposes including buying vehicle, for construction of house, marriage, education, etc. Table 12 shows that about 38 percent of workers have taken loan for constructing house. 10 percent of the workers have taken loan to meet health care expenditure and 10 percent for the education of the children. 8 percent of workers have taken loan for marriage purposes of their children. The main reason for their debt is inadequacy of income and growing expenditure.

Table 11. Distribution of workers by debt

Debt	No of female workers	Percentage
Yes	41	82
No	9	18
Total	50	100

Table 12. Purpose of debt

Purpose	No of female workers	Percentage
Health care	5	10
Construction	19	38
Education	5	10
Marriage	4	8
Others	8	16

Problems of the construction workers

Construction workers stick to their profession, even though construction activity forms part of the unorganized sector. Among the sample workers, 50 percent of the workers are having experience of 10-20 years and 26 percent of them having only below 10 years experience and 16 percent are having 20-30 years work experience and 8 percent of them are having experience of more than 30 years. There are so many problems which are faced by the workers in the construction sector. These problems are categorised under two heads-health problems and financial problems which is shown in the Table 13. Almost all the workers are suffering from health problems while 82 percent among them faces financial problem. 30 percent of the workers face other problems such as shortage drinking water facility and sanitary facility, poor living condition, long hours of work, gender discrimination and low wage.

Table 13. Distribution on the basis of problems faced by Construction workers

Problem	No of female workers	Percentage
Health Problem	50	100
Financial Problem	41	82
Others	15	30

Health problems

For women, the work in the construction sector is too risky and also there are so many problems faced by them at work place. Health problems related constitute the major problem for women workers because they are physically poor. The main health problems faced by them are given in Table 14. It is depicted in the table that out of the 50 samples, all are suffering from anyone of the health problems. About 60 percent of the workers having muscle pain and 12 percent of the workers are suffering from allergy. Workers who face the problem of coughed are 10 percent and asthma and breathing problem are found among 10 percent of workers. It could be noted that 8 percent of the workers are suffering from all these problems. If all workforces are suffering from health related problem, there will be a significant impact on productivity.

Table 14. Distribution of workers according to reported health complaints

Health Problem	No of female workers	Percentage
Muscle pain	28	60
Allergy	6	12
Asthma and breathing	5	10
Cough	5	10
All of the above	4	8
Total	50	100

Nature of hospital

There are many hospitals available in the district such as private hospitals, government hospitals

etc. The preference of the hospital by the worker is shown in the Table 15. Majority of the workers have preferred government hospital due to the availability of free medicine and free checkups. And also their financial status makes them incapable to afford costly treatment from private hospital. 8 percent prefer primary health centre and 4 percent prefer both private and government hospitals.

Table 15. Nature of hospital, construction workers preferred

Hospital	No of female workers	Percentage
Government	42	84
Private	2	4
Primary health centers	4	8
Both Government and Private	2	4
Total	50	100

Medical insurance

Provision of adequate social protection of workers engaged in informal sector is emerging as an important policy consideration throughout the world. Healthy and unhygienic work sites were major contributory factors towards health insecurity. Absence of adequate protection mechanism evolved either by the state or by the employers compounded the risk bearing confronted by the workers. As we know that the work is so risky in the construction industry there should be a need of taking a medical insurance. Table 16 reveals that about 72 percent of the workers in the sample are deprived of health security. Only 28 percent of workers are belonging to the group of having insurance. The construction work is highly risky, even though health is the important determinant of their jobs but most of them are not taking any health insurance policies, it is because of they are not aware of the health insurance.

Table 16. Distribution of workers on the basis of medical insurance

Medical insurance	No of female workers	Percentage
Yes	14	28
No	36	72
Total	50	100

Wage of the respondents

The wages given to the workers per day varies place to place and work site to work site. Table 17 shows that out of 50 samples, 38 percent of the workers have received the wages of ₹. 450 per day. 24 percent of the workers have only ₹. 400 wages per day. 22 percent of the respondents have got a wage of ₹. 500 per day while only 12 percent of the workers have got a wage of ₹. 600. And also 2 percent of workers have wage more than ₹. 600 per day. Table 18 shows the distribution of the respondents on the basis of gender discrimination in wage. It is clear from the table that 50 workers argued that there exists wage difference between men and women.

Table 17. Distribution on the basis of wage

Wage Class (in Rs.)	No of female workers	Percentage
400/day	12	24
450/day	19	38
500/day	11	22
550/day	1	2
600/day	6	12
650/day	1	2
Total	50	100

Table 18. Discrimination in wage

Wage difference	No of female workers	Percentage
Wage Discrimination Exist	50	100
No Wage Discrimination	0	0
Total	50	100

There are no much differences in the working hours of both men and women but they are not getting equal wages. On the other hand, wage satisfaction is considered, only 18 percent of the workers are satisfied with their wage whereas 82 percent of the workers are not satisfied. They have to work 8 hours and some are working for more than 8 hours. Least percentage of workers satisfied with the wage. They complain that they are not getting a wage for their effort. The membership of the women workers in the welfare board shows that almost 70 percent of the

workers have membership and about 30 percent of the workers not having a member in the welfare board. About 45.71 percent of the workers benefited from the board, some of the benefits are cash award, financial assistance for the marriage of their children, educational aid for SSLC students, etc. On the other hand, 54.2 percent of the workers are not benefited. It is found that out of total respondents, 52 percent of the workers are aware of the welfare programs given by the construction welfare board whereas 48 percent workers are not aware of it.

Suggestions

- Provide awareness about different welfare scheme to workers and need to have an adequate intervention from the government authorities required ensuring the health, safety and welfare of the construction workers.
- Encourage the construction workers saving habit through initiating banking awareness and ensure adequate insurance facilities for the construction workers.
- Ensure equal wage for the work in the unorganised sector and renew the wages yearly.
- Give proper guidelines and awareness about medical insurance, various schemes and financial support, programme offered through welfare board and initiative workers to take membership in the welfareboard.
- To create regulatory body or a grievance redressal to handle various issues, problems and complaints of women workers in the construction field.
- Lack of skill and higher education are the matters to prefer this risky job by women workers. Providing training and skill development will helps them to choose better jobs.

Conclusion

The construction industry in India stands as an important contributor of the development as it creates investment opportunities across the various related sectors. Construction industry has been providing seven percent of total world employment. Literacy rate, life expectancy and many other indicators show that Odisha women are far ahead of their counter parts in the rest of India. Female employment has been regarded as a central vehicle related to improvement in women status. According to Census 2011, there were 14 districts, 63 TALUKS, 520 towns and 1018 villages in the State of Odisha. The total population of Odisha is 3,34,06,061 with 1,60,27,412 males and 1,73,78,649 females and the total number of households in Odisha is 78,53,754. The females work participation rate is 18.23 percent. On the other hand, census data on Kendrapara district has shown that the district has a population of 2,525,637 and 31 percent (about 5 lakh) population engaged in either main or marginal works. It could be emphasised that about 50 percent male and 14 percent female population are working population. The provision of adequate social protection for workers engaged in informal sector is emerging important policy considerations throughout the world especially for women; it is in this context that an attempt whose made in this study to examine the question of social protection for informal sector through an analysis of factors like working conditions, security of employment etc. The study was based on empirical information generated through a primary survey in Kendrapara district. It should be recognized that the workers need to have a good working condition, receive a minimum wage and access to a minimum amount of social security.

The main problems faced by them are the lack of security, there is no security for their life in the workingsite. Some other problems faced by them are the health and financial problems. There is a working of a welfare board for the construction workers while many are not aware of this scheme and also the members in this board are unaware of the benefits. The χ^2 test result shows that the wage is not paid based on the age or the years of experience of the workers. The workers need the safeguard for their life and also getting a maximum benefit from their work this is because to support their family and children. There is a scope to conduct an in depth study in future to know the working condition of the women construction workers.

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PROJECT REPORT ON " SOCIO-ECONOMIC CONDITION OF WOMEN
CONSTRUCTION WORKERS IN KENDRAPARA DISTRICT, ODISHA"

DEPARTMENT OF ECONOMICS

PATTAMUNDAI COLLEGE, PATTAMUNDAI

SESSION 2021-22

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11	Sudhee Rajasree Barik	BA19-246	Sudhee. Rajasree Barik
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Pradyuman Pradhan
15/05/22

DEPARTMENT OF ODIA
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PROJECT



ACADEMIC SESSION -2021-2022

TOPIC: - "SRI JAGANNATHA IN UTKALIYA CULTURE
(UTKALIYE SANSKRUTIRE SRI JAGANNATHA)

GUIDE: - MR. PRAMOD KUMAR SWAIN, READER IN ODIA

DEPARTMENT OF ODIA

PATTAMUNDAI COLLEGE, PATTAMUNDAI DIST-KENDRAPARA-754215.

PROJECT REPORT

The Project Report is submitted as the evidence of tasks that are undertaken and accomplished by the 6th Semester Students of Odia Department while perusing their Projects Work on the **Topic " SRI JAGANNATH IN UTKALIYA CULTURE (Utkaliye Sanskrutire Sri Jagannatha)** during the academic session 2021-2022 in the month of May-2022. The Students of this Department visited Jagannatha Temple, Bagabat Tungi (Where Srimad Bhagabat is recited in regular way) of three Villages of the Locality & interacted with the elderly persons of the Villages, how they realise the existence and importance of Lord Jagannath in Village Cultures . The Project was guided by **Mr. Pramoad Kumar Swain, Reader in Odia** and the students presented their Project Report before the External Examiner & other faculty members for final evaluation.

Pramoad Kumar Swain
Signature of the Guide
3.7.2022

Devi Kumar Mahapatra
Signature of the External Examiner
Date: 03/07/2022

ଓଡ଼ିଆ ପଢ଼ାଘର

[Signature]
Principal
3-7-22
Principal
Pattamundai College

ସୂଚନା

- | <u>କ୍ର.ସଂ</u> | <u>ବିଷୟ</u> |
|---------------|-----------------------------|
| (୧) | ପଞ୍ଚମ ଶ୍ରେଣୀ / ଉଚ୍ଚଶିକ୍ଷା । |
| (୨) | ଶ୍ରୀ ଜଗନ୍ନାଥ ପଞ୍ଚମ ଶ୍ରେଣୀ । |
| (୩) | ମହାତ୍ମ୍ୟଙ୍କର ବିଭିନ୍ନ କେଶ । |
| (୪) | ମହାତ୍ମ୍ୟଙ୍କର ବିଭିନ୍ନ ଲାଠୀ । |
| (୫) | ନିର୍ଦ୍ଦେଶ । |

ପ୍ରଶ୍ନୋତ୍ତର ଆନୁଷ୍ଠାନିକ ଭାଗ -

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- ୧୨) ଲିଭାଦ୍ୱାରା ବା ଖୋଦ୍ଦ୍ୱାରା ଲବ୍ଧ୍ୟ ବିଦ୍ୟାବୃଦ୍ଧି ।
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- ୧୪) ଶୁଣି ଓ ନୀତିକ୍ରମର ଉତ୍ପାଦନ ।
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- ୧୧୦) ଲାଭକାରୀ ପୂର୍ବକରା ବିଶ୍ୱାସରେ ଏକଜ୍ଞାନରେ ମୁକାବିଲା କରିବାର ସାମର୍ଥ୍ୟ ।
- ୧୧୧) ପ୍ରତ୍ୟକ୍ଷ ଉତ୍ପାଦନ ବିକଳ; କିନ୍ତୁ ପ୍ରଶ୍ନୋତ୍ତର ଉତ୍ପାଦନ ।
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- ୧୧୩) ପ୍ରଶ୍ନୋତ୍ତର ପ୍ରକାର କାର୍ଯ୍ୟକୁ ପ୍ରଗତିଶୀଳ ଏକଜ୍ଞାନରେ କରେ ।
- ୧୧୪) ପ୍ରଶ୍ନୋତ୍ତର କାର୍ଯ୍ୟକୁ କାର୍ଯ୍ୟର ପ୍ରଗତି ଉପରେ ଏକଜ୍ଞାନ ବିକଳ ।
- ୧୧୫) ପ୍ରଶ୍ନୋତ୍ତର ଉତ୍ପାଦନ ପ୍ରକାର ।
- ୧୧୬) ପ୍ରାକୃତିକ ଉତ୍ପାଦନ ପ୍ରକାରର ମୂଲ୍ୟ ପ୍ରଦାନ ।

ଦାଣ୍ଡଦେବତା ଶ୍ରୀଜଗନ୍ନାଥ:-

ଦାଣ୍ଡଦେବତାଙ୍କ ବିଗ୍ରହ ନିୟତାଠାରେ ନିର୍ଦ୍ଦେଶ । ତେଣୁ ତୁମ ଦ୍ଵାଦଶମାତ୍ର ଉପାସନା
 ଉପରେ ନିୟତାଠା ଶ୍ରୀ ଜଗନ୍ନାଥଙ୍କ ବିଗ୍ରହରେ ଭାବିତାଣ ଦେଖୁଛୁ । ତୁମ ଦ୍ଵାଦଶମାତ୍ର ନିର୍ଦ୍ଦେଶ
 ପ୍ରମାଣ ଖାତାରେଲକ ଦ୍ଵାଦା ଦୁଇଗୁଣ ଦୋହାଦ୍ଵାରା ପ୍ରାଣପୁରାଣା ଶିଳାଲେଖରେ ଦେଖିବାକୁ ମିଳେ
 ଚନ୍ଦ୍ର ଶିଳାରେ ଯେତେ ଲୋ ପ୍ରମାଣ ଖାତାରେଲକ ଦ୍ଵାରା ଲେଖା ଖର୍ଚ୍ଚରେ ଦୁଇ , ଶତ , ନିମ୍ନ ,
 ଚନ୍ଦ୍ର ଶିଳାରେ ଭାବୁଥିବାର କଳ୍ପଦୁଇ ପ୍ରକୃତ କଳିକାକୁ ଦେଖିଲାଗିଥିଲେ । ଚନ୍ଦ୍ର କଳି
 ତୁମ ଚୈତନ୍ୟମାନଙ୍କର ଯୋଗ୍ୟତା ସ୍ଵରୂପେ କେତେକ କୈଳିଗୁଡ଼ିକୁ କଥାଲାଭ । କେତେକ
 ପ୍ରକୃତ ନୃପେ , ଚୈତନ୍ୟ ମଧ୍ୟ ଭୃଗୁ କଳିର ଦୁର୍ଦ୍ଦଶାକୁ ନିରାକରଣ ଯଦୁବୀରୀ ଓ ଉଦୟଗିରି
 ଶୃଙ୍ଗୀରେ ଭାବୁଥିବାର କଳ୍ପଦୁଇର ଯେତେ ଦେଖିବାକୁ ମିଳେ । ଚନ୍ଦ୍ର ଶିଳାରେ କୈଳିମାନଙ୍କ
 ତୁମ ଚୈତ୍ୟ ଦ୍ଵାଦଶମାତ୍ର ନିର୍ଦ୍ଦେଶ । ଦୈନିକ୍ୟରେ ମଧ୍ୟ ତୁମ ଦ୍ଵାଦଶମାତ୍ର ନିର୍ଦ୍ଦେଶ
 ଦେଖିବାକୁ ମିଳେ । ତାହାଣ କୃତ୍ୟ ଦେଖି କଳିରୁ ଯୋଗ୍ୟ କରୁ ଶାନ୍ତିପ୍ରାପ୍ତି ଓ ନିର୍ଦ୍ଦେଶ
 ଭାର୍ତ୍ତବ୍ୟ ଇତ୍ୟାଦି ତୁମମାନଙ୍କର ଦୋହାଦ୍ଵାରା ଦୈନିକ୍ୟରେଲକମାନେ ଚନ୍ଦ୍ରକୁ ଦୋହାଦ୍ଵାରା
 ଚୈତ୍ୟ ଦ୍ଵାଦଶମାତ୍ର କରୁ । କିନ୍ତୁ ଭାବି ଜାଣିଲେ 'ତୁମଦେବତା'ଙ୍କ ନାମୋଚ୍ଚ୍ଵାସ ପୂର୍ବେ
 ମଧ୍ୟ ଛାଦା ସର୍ବ ଦେଖି ତୁମ ଦେବତା ଦେଖି ଦର୍ଶନ ଯେ । ଦିନିକ୍ୟରେ ମଧ୍ୟ ତୁମ
 ଦ୍ଵାଦଶମାତ୍ର ପ୍ରକୃତ ନିର୍ଦ୍ଦେଶ ଭାବି ଦୃଷ୍ଟି ପୁଠ । ଦିନିକ୍ୟରେ ଯାଦୁମତ୍ୟ ଶ୍ରୁତ ଦ୍ଵାଦଶମାତ୍ର
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 ଚକ୍ର ବିଷ୍ଣୁ , ଲାଦାଠା ପ୍ରକୃତରେ ବିଷ୍ଣୁକର୍ମା ଉପରେ ଚନ୍ଦ୍ର ସ୍ଵରୂପ ନିର୍ଦ୍ଦେଶ କରୁଥିଲେ ।
 ଚନ୍ଦ୍ର ଚୈତ୍ୟ ପ୍ରକୃତ୍ୟ ମଧ୍ୟରୁ ଯେତେ ଦେଖି , ଛାଦୋଗ୍ୟ ଦୈନିକ୍ୟ , ଶତଦାସ ପ୍ରାପ୍ତ
 ଚୈତ୍ୟ ମଧ୍ୟ ତୁମ ଦ୍ଵାଦଶମାତ୍ର ପ୍ରକୃତ୍ୟ ସୂଚନା ମିଳେ । ଭୃଗୁ ଲୁଗାରେ ଲେଖା ପ୍ରକୃତ୍ୟ
 ଭୃଗୁ ଚୈତ୍ୟ ଦେଖୁଛୁ ତନୁମଧ୍ୟରେ ମହାଦ୍ଵାର , ପ୍ରହୁଭୃଗୁ , ମହା ଭୃଗୁ , ଦ୍ଵିବିଜା
 ଭୃଗୁ , ଶୁକଭୃଗୁ , ସୁନଭୃଗୁ ଯାଦୁରେ ତୁମ ଦ୍ଵାଦଶମାତ୍ର ଦେଖିବାକୁ ମିଳେ ।
 ମହାଦ୍ଵାର ପ୍ରକୃତ୍ୟରେ ଦେଖିଲେ , ଯାଦୁ ଦୈନିକ୍ୟ ଚନ୍ଦ୍ର ଦାନକରେ ଲାମଦୈନିକ୍ୟ
 ପୁଠ । ପ୍ରହୁ ଭୃଗୁରେ ଶୁକଭୃଗୁ 'ପ୍ରକୃତ୍ୟ ଦୈନିକ୍ୟ' ଚୈତ୍ୟ ଭୃଗୁ ଭାବୁଥିବା କଥା
 ଦେଖିଲେ । ଭୃଗୁ ପ୍ରକୃତ୍ୟରେ ତୁମ ଦ୍ଵାଦଶମାତ୍ର ପ୍ରକୃତ୍ୟରେ ଚନ୍ଦ୍ର ଦୈନିକ୍ୟ ପୂର୍ବେ ମଧ୍ୟ
 କାଳକ୍ରମେ ଚନ୍ଦ୍ର ଓଦିନା ପ୍ରକୃତ୍ୟରେ ପ୍ରକୃତ୍ୟ କରୁ ।

ସ୍ୱାମୀ ପ୍ରକାଶିତ ବିକଳମାନ ଦେହା:- ଭୃଗୁଧାରୀଭୋଜି ଦ୍ୱାଜକେଶ (ସ୍ୱାମୀ ଦ୍ୱାଜା କେଶ),
ସ୍ୱାମୀ ଦ୍ୱାଜା କେଶ (ସ୍ୱାମୀ ନବିନୀ), ଶ୍ରୀଧିକେଶ (ମାର୍ଗଣୀର କୃତ୍ୱା ଚନ୍ଦ୍ରକେଶ), ଭୀଷ୍ମସ୍ୱାମୀ
କେଶ (ନାଗାର୍ଜୁନ କେଶ) ।

ନୃସିଂହ ବିକଳମାନ ଦେହା:- ଧ୍ୟାୟକେଶା କେଶ ।

ସମାଜ ସାହିତ୍ୟରେ କେଶ:- ସମାଜ ଭାଷାରେ ସମାଜକୁ ମଧ୍ୟ ବିଭିନ୍ନ କେଶରେ ପ୍ରକାଶାତ ।
କେଶ ସମାଜରେ କେଶକେଶ, ଧ୍ୟାୟକେଶ ଇତ୍ୟାଦି ନବିନୀକେଶ କେଶ, ଶାନ୍ତ ସମାଜରେ
କୋଟକାଶି କେଶ, ଧ୍ୟାୟ ଶାନ୍ତ ସମାଜରେ କାମାକ୍ଷୀ କେଶ କଥାକାତ ।

ସୁନାକେଶ:-

ଶ୍ରୀ ଜଗନ୍ନାଥ କର୍ତ୍ତବ୍ୟ ଚର୍ଚ୍ଚା ଦ୍ୱାଜକେଶ ଦୁଇଟି । ମଧ୍ୟ ଭାଗରେ ସୁନାକେଶ
(କୋଟାକେଶ କୃତ୍ୱା ଧ୍ୟାୟକେଶ) ପ୍ରକୃତ ସୁନା ଓ ପ୍ରକୃତକେଶ । ଧ୍ୟାୟ ସୁନାକେଶରେ ସମାଜକୁ
ସୁନାକେଶ କର୍ତ୍ତବ୍ୟ ଦୁଇଭାଗ ଶାନ୍ତ ଦେହା ଧ୍ୟାୟ କେଶ ଧ୍ୟାୟକେଶ ଧ୍ୟାୟ କେଶ ।
କୋଟାକେଶ କର୍ତ୍ତବ୍ୟ ଦିନ ଭୃଗୁଧାରୀଭୋଜି କେଶ ଦ୍ୱାଜା ସ୍ୱାମୀ ଦ୍ୱାଜାରେ ସମାଜକୁ ସୁନାକେଶ
ଦୁଇଟି । ଧ୍ୟାୟକେଶ କର୍ତ୍ତବ୍ୟ ସମାଜକୁ ସୁନାକେଶ ଦୁଇଟି ।

ଶ୍ରୀଧିକେଶ:-

ସମାଜକୁ ଲୋକମାନଙ୍କୁ ଶିକ୍ଷାଦେବା ଧ୍ୟାୟ କେଶ ଭିନ୍ନ ଭିନ୍ନ ଭାଗରେ ଶ୍ରୀଧି
କେଶ ନିମନ୍ତେ ଶ୍ରୀଧିକେଶ ଦୁଇଟି । ସମାଜକୁ ଶିକ୍ଷା ଦେବା ଶ୍ରୀଧି କେଶ ଦୁଇଟି ।
ଧ୍ୟାୟ ଶ୍ରୀଧି ମାର୍ଗଣୀର କୃତ୍ୱା ଚନ୍ଦ୍ରକେଶ ଦିନ ଧ୍ୟାୟ ଦେହା ଧ୍ୟାୟକେଶ ଓ ଧ୍ୟାୟକେଶ
ସମାଜ । ମାର୍ଗଣୀର କୃତ୍ୱା ଚନ୍ଦ୍ରକେଶରେ କେଶକେଶ ଓ ଧ୍ୟାୟକେଶ, ଧ୍ୟାୟକେଶରେ
ଧ୍ୟାୟକେଶ କୋଟାକେଶ (ସମାଜରେ ସ୍ୱାମୀ ଦ୍ୱାଜାରେ) ଓ ଧ୍ୟାୟକେଶ କେଶକେଶ
ଧ୍ୟାୟକେଶ ଓ ନିମି ଧ୍ୟାୟକେଶ ଶ୍ରୀଧି ଦିନ କୃତ୍ୱା ଦ୍ୱାଜାରେ ।

ଧ୍ୟାୟକେଶ ସମାଜକୁ ଧ୍ୟାୟକେଶ କେଶେ ସୁନାକେଶ, ସୁନାକେଶ ସାଧ୍ୟକେଶ, ସାଧ୍ୟକେଶ
ଧ୍ୟାୟକେଶ ଓ ସାଧ୍ୟକେଶ କେଶେ ସୁନାକେଶ । ସାଧ୍ୟକେଶ କୋଟାକେଶ କେଶ
କେଶେ ଶାନ୍ତ କୋଟାକେଶ କୋଟାକେଶ କୋଟାକେଶ କୋଟାକେଶ । ଧ୍ୟାୟକେଶ କୋଟାକେଶ
ସମାଜକୁ କୃତ୍ୱା କୋଟାକେଶ କେଶ କଥାକାତ । ଧ୍ୟାୟକେଶ କୋଟାକେଶ କେଶ କଥାକାତ ।

ମହାପ୍ରଭୁଙ୍କର ବିଭିନ୍ନ ବିଶେଷ:-

କଟକ୍ଷିପ୍ତାଦି:- ଗୁଣିତନ ଗ୍ରାହରେ ମହାପ୍ରଭୁ କଟକ୍ଷିପ୍ତାଦି ବିଶେଷ ହୁଏ ।

କୌଶାଳ :- ଚନ୍ଦ୍ର ବିଶେଷ ଲାଗିଲୁ ଚୂଡ଼ାଲୁକୁ ୨୧ ଦିନ ଭାର୍ଗବ ମହାପ୍ରଭୁ ହୋଇଥାନ୍ତି ।

କେମ୍ବୁ :- ଶୁକ୍ଳ ଭୂର୍ଗୁଣାରେ ମହାପ୍ରଭୁ ଶ୍ରୀ ଜଗନ୍ନାଥ ଦାଣ୍ଡବିଶେଷ ହୁଏ ।

ଲୋଭା :- ନବଲୋକ ବିଶେଷ ଲୋକସମ୍ପର୍କ ଭାବେ ହୁଏ । ସୁନାବିଶେଷ (ଲୋଭା ଶୁକ୍ଳ ଲୋଭା), ଦଶଦିନୀ, କାର୍ତ୍ତିକ ଭୂର୍ଗୁଣା, ଭାଗ୍ୟଶୁନ ଭୂର୍ଗୁଣାରେ ମହାପ୍ରଭୁ ସୁନା ବିଶେଷ ହୁଏ ଓ ଲୋଭା ଭୂର୍ଗୁଣାରେ ଶ୍ରୀଜୀଉଙ୍କର ଭାବେ ସୁନାବିଶେଷ ହୁଏ ।

ଶ୍ରୀକା :- ଚିତାକାଶି ବିଶେଷ ମହାପ୍ରଭୁ ଶ୍ରୀକାଶି ଲୋକାକାଶ୍ୟାରେ ହୋଇଥାନ୍ତି ।

ଦ୍ରାପ୍ତ :- ଦ୍ରାପ୍ତରେଣା କାଶି (ଦୁର୍ଲ୍ଲଭାଦିନୀ), ବିଚାରୋକ୍ତି ବିଶେଷ (କୃଷ୍ଣ ଦଶମୀ), ଜାକୀର୍ଣ୍ଣଦଳ ବିଶେଷ (କୃଷ୍ଣ ଲୋକାକାଶ୍ୟା), ଭୂଲକ୍ଷ୍ମୀସ୍ତ୍ରୀ ବିଶେଷ (କୃଷ୍ଣ ଦ୍ଵାଦଶୀ), ଦ୍ଵାପକଳିଦ୍ଵାପ ବିଶେଷ (କୃଷ୍ଣ ତ୍ରୟୋଦଶୀ), ବିଳିକାମି ବିଶେଷ (କୃଷ୍ଣ ଚତୁର୍ଦ୍ଦଶୀ) ।

ଲୋକ୍ଷି :- ବିଜୟା ଦଶମୀ ଗ୍ରାହବିଶେଷ ଶ୍ରୀ ଜଗନ୍ନାଥ ଧାରଣ କରିଥାନ୍ତି ।

କାର୍ତ୍ତିକ :- ଦ୍ଵାପାଦାକାଶ୍ୟାରେ ବିଶେଷ (ଲୋକ୍ଷି ଶୁକ୍ଳ ଲୋକାକାଶ୍ୟାରେ କାର୍ତ୍ତିକ ଶୁକ୍ଳ ଦଶମୀ ଭାର୍ଗବ), ଲକ୍ଷ୍ମୀ ନାମାକାଶ୍ୟା ବିଶେଷ, ଲକ୍ଷ୍ମୀ ନୃସିଂହ ବିଶେଷ, (ଶୁକ୍ଳ ଚତୁର୍ଦ୍ଦଶୀ), ବିଳିକା ବିଶେଷ (ଶୁକ୍ଳ ଦ୍ଵାଦଶୀ), ଭାଗ୍ୟଦ୍ଵାପ ବିଶେଷ ବା ନାଗାର୍ଜୁନ ବିଶେଷ (କାର୍ତ୍ତିକ ଦଶମୀ ୨୧ଦିନ), ଗ୍ରାହାଗ୍ରାହେଣ୍ଡୁ ବିଶେଷ (କାର୍ତ୍ତିକ ଭୂର୍ଗୁଣା) ।

ମାର୍ଗଶୀ :- ଶ୍ରୀକାଶି (ମାର୍ଗଶୀର କୃଷ୍ଣ ଚତୁର୍ଦ୍ଦଶୀ, ଲୋକାକାଶ୍ୟା ଓ ଶୁକ୍ଳ ଦ୍ଵାଦଶୀ) ଲୋକାକାଶ୍ୟା ବିଶେଷ (ମାର୍ଗଶୀର ଶୁକ୍ଳ ଲକ୍ଷ୍ମୀ ଠାରୁ କ୍ଷତ୍ର ଭାବେ ଭାର୍ଗବ) ମହାପ୍ରଭୁ ଜଗନ୍ନାଥ ଧର୍ମ ବିଶେଷର ମୂଳ ହୋଇଥାନ୍ତି ।

କୌତା :- ଭୂତ୍ୟାକ୍ରିତେକ ବିଶେଷ ମହାପ୍ରଭୁ ଶୈବ ପୂର୍ଣ୍ଣିମାରେ ଦେଖାଯାନ୍ତି ।

ମାଳା :- ଭଦ୍ରବିଶେଷ (ଶୁକ୍ଳ ଦ୍ୱିତୀୟା) , ଶକରଝାଞ୍ଜଳ ବିଶେଷ (ମାଘପୂର୍ଣ୍ଣିମା) , ନିବାଳ ବିଶେଷ (ମଙ୍ଗଳ ପ୍ରତ୍ୟହା ଦୂର୍ଜୟନ) , ମଙ୍ଗଳ ବିଶେଷ (ମଙ୍ଗଳ ପ୍ରତ୍ୟହା) , ଚନ୍ଦ୍ରପାଦ ବିଶେଷ ମାନ ଧାରଣ କରନ୍ତି ।

ଭୋକ୍ତିଗୁଣ :- ଶାନ୍ତେଶ ବିଶେଷ (ଶୁକ୍ଳ ନବମୀତୀରୁ ପୂର୍ଣ୍ଣିମା ଦର୍ଶନ) , ସୁନାବିଶେଷ (ଭୋକ୍ତିଗୁଣ ପୂର୍ଣ୍ଣିମା) , ମହାପ୍ରଭୁ ଧର୍ମ ବିଶେଷମାନ ଧାରଣ କରନ୍ତି ।

ଶୋଭା :- ସ୍ୱାମୀଦେବୀ ବିଶେଷ (ସ୍ୱାମୀନବମୀ) ରେ ଶୁଣି ଜଗନ୍ନାଥ ଧାରଣ କରନ୍ତି ।

ଠାକୁର ମାନଙ୍କର ବିଷୟ :-

୧) ଶାନ୍ତେଶ ବିଶେଷ :- ୧୨ ଦ୍ୱାଦଶ ଚନ୍ଦ୍ର ନାଲି ସିଲିକ ଲୁଗାରେ ଶାନ୍ତେଶ ବିଶେଷ କୃତାନ୍ତର ଧାରଣ । ଧର୍ମା ଶକ୍ତିପୁର ବିଶେଷରେ ଧାରଣ ।

୨) ସୁନାବିଶେଷ :- ଧାଳି ସିଲିକ ଲୁଗା ଭଦ୍ର ପ୍ରମାଣରେ ମହାପ୍ରଭୁଙ୍କର ଧାରଣ ।

୩) ନିବାଳ ବିଶେଷ :- ଶୁଣି ଜଗନ୍ନାଥ ସ୍ନାନ ପ୍ରମାଣରେ ନିବାଳ ଦୁଧ । ଧର୍ମା ଚନ୍ଦ୍ର ୧୦ ଟଙ୍କା ପ୍ରସାଦ ଚନ୍ଦ୍ର । ଧର୍ମ ଲୁଗା ସୁନାଲୁଗା , କମଳା ଓ ଧାଳିମିଶା ପ୍ରସାଦ ।

୪) ମଙ୍ଗଳ ବିଶେଷ :- ମହାପ୍ରଭୁଙ୍କର ଧର୍ମା ୨୪ ଟଙ୍କା ଚନ୍ଦ୍ର ସିଲିକ ଲୁଗା ଧାରଣ କରି ବ୍ୟବହାର ଦୁଧ ।

୫) ଚନ୍ଦ୍ରପାଦ ବିଶେଷ :- ୧୨ ଟଙ୍କା ଚନ୍ଦ୍ର ଓ ୩ ଟଙ୍କା ପ୍ରସାଦ ସିଲିକ ଲୁଗା ମହାପ୍ରଭୁଙ୍କର ଧାରଣ କରନ୍ତି ।

୧) ଦେଶାଭିମାନୀ :- କୌଣସି ଦାମାଦନୀରୁ ଗୁଣଗୁଣିତା ଚଳାଏଣୁ ଚଳୁଥିବା ଭୂମି ଓ ଚଳୁଥିବା ପ୍ରକାରର ଭୂମି ବିଭାଜନ । ଏହି ଭୂମିରେ ପୂର୍ବରୁ ଥିବା ଭୂମି ଜଗନ୍ନାଥକୁ, ନାହିଁ ଥିବାରୁ ଭୂମିରେ ଓ କଳା ପରି କଳିପ୍ରକୃତି ବିଭାଜନ ।

୨) ବେଗେଟି :- ମହାପ୍ରଭୁଙ୍କ ମଙ୍ଗଳ ଲାଳିତ୍ୟ ପ୍ରକାରର ବ୍ୟବହାର ଦୃଷ୍ଟ ।

୩) ଭାଟଭଜନୀ :- ଶ୍ରୀ ଜଗନ୍ନାଥଙ୍କ ସ୍ତୁତି ଭୂମି ଭାଟଭଜନୀ ଦେଖାଯାଏ । ଚନ୍ଦ୍ର ଶିଳାରେ ଡିଆଁରି ଚନ୍ଦ୍ର ମିଶ୍ର ଭୂମି ।

୪) ବିଭକ୍ତିଭାଟ :- ଚନ୍ଦ୍ର ଭୂମି ଜଗନ୍ନାଥଙ୍କୁ ସୁକ୍ଷିଣୀ ବିଭକ୍ତ ପ୍ରକାରର ବିଭାଜନ ।

୫) କେଶବୃକ୍ଷ :- ଚନ୍ଦ୍ର ଭୂମି ପ୍ରକାରର ଭୂମି ଓ ଚଳୁଥିବା ଭୂମି । ଚନ୍ଦ୍ର ଭୂମି ମହାପ୍ରଭୁଙ୍କ ଉପସ୍ଥିତିରେ ଉପକାର ଦୃଷ୍ଟ ।

ଦୋହ ଭାଗୀ :- ମହାପ୍ରଭୁ ପ୍ରକାରର ବିଭିନ୍ନ ବ୍ୟବହାର ବିଭିନ୍ନ ପ୍ରକାରର ଦୋହ ବିଧିଧାନ ।

ରାଜ୍ୟର ଦାନ - ଭାଲି ପ୍ରକାରର ଦୋହ ଶ୍ରୀ ଜଗନ୍ନାଥଙ୍କୁ ବିଭାଜନ ଦେଖାଯାଏ ।

ପ୍ରୋମକାର ଦାନ - କଳା ଭୂମି ମିଶ୍ରା ଶୁକ୍ଳ ଦୋହ ବିଧିଧାନ ।

ମଙ୍ଗଳକାର ଦାନ - ଉପକାର ଦୋହ ମହାପ୍ରଭୁ ବିଧିଧାନ ।

ଦୁଧକାର ଦାନ - ନୀଳ ପ୍ରକାରର ଦୋହ ବିଭାଜନ ।

ଗୁରୁକାର ଦାନ - ପ୍ରକାର ପ୍ରକାରର ଦୋହ ବିଧିଧାନ ।

ଶୁକ୍ରକାର ଦାନ - ଶୁକ୍ଳ ପ୍ରକାରର ଦୋହ ମହାପ୍ରଭୁ ବିଧିଧାନ ।

ଗଣକାର ଦାନ - କଳା ପ୍ରକାରର ଦୋହ ଶ୍ରୀ ଜଗନ୍ନାଥଙ୍କୁ ବିଭାଜନ ।

ମହାତ୍ମାଙ୍କର ଦ୍ଵାଦଶ ଲାଠା :-

ଶ୍ରୀ ଜଗନ୍ନାଥ ଲୋକରେ କାର୍ଯ୍ୟରେ ଚୋର ଲାଠା ଦେଖାଯାଏ ।

ପ୍ରେମପୂର୍ଣ୍ଣ ଦେଲା -

- ୧) ସ୍ଵାମୀଲାଠା - କୋଷ୍ଠ ଭୂଷଣୀ ।
- ୨) ଶ୍ରୀଗୁଣ୍ଡିଚା - ଘୋରାଣ ଶୁକ୍ଳ ଦୁଃଖିନୀ ।
- ୩) ଦେବୀଲୀଳା ଲାଠା - ଘୋରାଣ ଶୁକ୍ଳ ଧର୍ମାତ୍ମା ।
- ୪) ଦଳିତାଲୀଳା ଲାଠା - ଦଳିତାଲୀଳା ପ୍ରଫୁଲ୍ଲୀ ।
- ୫) ଭୀଷଣ ଭୀଷଣୀ - ଭୀଷଣ ଶୁକ୍ଳ ଧର୍ମାତ୍ମା ।
- ୬) ଦେବୋତ୍ସାହାସିନୀ - କାର୍ତ୍ତିକ ଶୁକ୍ଳ ଧର୍ମାତ୍ମା ।
- ୭) ବ୍ରାହ୍ମଚାରୀ ଲାଠା (ଗୋବିନ୍ଦ) - ମାର୍ଗଶୀର ଶୁକ୍ଳ ଭୀଷଣୀ ।
- ୮) ଭୃଗୁପୁତ୍ରା - ଭୃଗୁ ଭୂଷଣୀ ।
- ୯) ବ୍ରହ୍ମାଣ୍ଡ - ମକର ପ୍ରଫୁଲ୍ଲୀ ।
- ୧୦) ଦୋଳଭୂଷଣୀ - ଦୋଳ ଭୂଷଣୀ ।
- ୧୧) ଦମନ ଗୋବିନ୍ଦ ଭୂଷଣୀ - ଗୋବିନ୍ଦ ଶୁକ୍ଳ ଶତ୍ରୁଘ୍ନୀ ।
- ୧୨) ଚନ୍ଦନ - ଗୋବିନ୍ଦ ଶୁକ୍ଳ ଦୁଃଖିନୀ ଓ ଚନ୍ଦନ ବ୍ୟାଜୀ କାହାଣୀ ଚନ୍ଦନ ଘାଟରେ ଓ ଚନ୍ଦନ ଦିଶରେ ଚନ୍ଦନ ।
- ୧୩) ନୀଳାଦ୍ରୀ ମହୋଦଳ - ଗୋବିନ୍ଦ ଶୁକ୍ଳ ସାଧୁମଣୀ ।

ଜଗନ୍ନାଥଙ୍କ ଉପାଳାପା ଦେଉଳ ସମ୍ପର୍କେ ମାତ୍ର ।

ସ୍ଥାନଲାପା :-

ଜ୍ୟେଷ୍ଠମାସ ଚୂଡ଼ିମା ଦିନ ମହାପ୍ରଭୁଙ୍କ ସ୍ଥାନଲାପା ଘାଟିଃ ଦୁର୍ଗ । ଧର୍ମ ଦିନ ମହାପ୍ରଭୁ ଉତ୍ତମୋତ୍ତମ ଧର୍ମ ଅଦୃଷ୍ଟି ଦ୍ଵାରା ଶୁଣ ମନ୍ଦିରର ଘାଟିର ମଧ୍ୟରେ ଥିବା ସ୍ଥାନ ମନ୍ତ୍ରଦ୍ଵାରା ବିଚିତ୍ କରନ୍ତି । ସ୍ଥାନନାଟ ନିମନ୍ତେ ମନ୍ଦିରର ଦ୍ଵାର ଦ୍ଵାର ନିକଟସ୍ଥ ଶାନ୍ତି ଠାକୁରାଣୀଙ୍କ ସମ୍ମୁଖରେ ଥିବା ସୁନାକୁଣ୍ଡରୁ ୧୦୮ କଳସ ଜଳରେ ଶୁଣ ଜଗନ୍ନାଥ, କଳସପୁ, ସୁଦ୍ରା ଓ ସୁଦର୍ଶନ ସ୍ଥାନ କରାଯାନ୍ତି । ସ୍ଥାନ ବିଧାନ ଭରେ ଗୋଦାନିତ୍ୟର ମଠରୁ କଳସପୁଙ୍କର ଓ ଶ୍ରୀରାଜଦାସ ମଠରୁ ଶୁଣ ଜଗନ୍ନାଥଙ୍କ ଓ ସୁଦ୍ରାଙ୍କ ନିମନ୍ତେ ଦ୍ଵାଦଶବେଣର ଦ୍ଵାରଦ୍ଵାରା ଘୋଡ଼ାଲୋକ ମହାପ୍ରଭୁଙ୍କୁ ଦ୍ଵାଦଶବେଣ କରାଯାଏ । ଧର୍ମ ବିଧାନକୁ ଗଣାବେଣ ଗୋଳି ମଧ୍ୟ କରନ୍ତି ।

ସେବାପ୍ରଣା :-

ସେବାପ୍ରଣା ନୀତି ଜ୍ୟେଷ୍ଠ ଚୂଡ଼ିମା ଭରଣରୁ ଘୋଡ଼ା ମାସ ଘୋଡ଼ାପ୍ରଣା ଅର୍ଚ୍ଚନା ଦୁର୍ଗ । ଧର୍ମ ପ୍ରମାଣରେ ଠାକୁରମାନଙ୍କୁ କେନ୍ଦ୍ର ଦର୍ଶନ କରାଯାନ୍ତି ନାହିଁ । ଠାକୁରମାନେ ଧର୍ମ ପ୍ରମାଣରେ ଠାକୁରମାନଙ୍କୁ କେନ୍ଦ୍ର ଦର୍ଶନ କରାଯାନ୍ତି ନାହିଁ । ଠାକୁରମାନେ ଧର୍ମ ପ୍ରମାଣରେ ଘୋଡ଼ା ପାଆନ୍ତି । ମନ୍ଦିରର ଦ୍ଵାର ଦ୍ଵାର ନିକଟସ୍ଥ ଶାନ୍ତି ଠାକୁରାଣୀଙ୍କ ସମ୍ମୁଖରେ ଥିବା ସେବାପ୍ରଣା ୧୫ ଦିନ ମଧ୍ୟରେ ଜ୍ୟେଷ୍ଠ କୃଷ୍ଣ, ଅକ୍ଟମୀରେ ଘୋଡ଼ାପ୍ରଣା ହାରି, ଦଶମୀରେ ଚକାଶିକେ, ଧନୁରାଶ୍ୟ ଚନ୍ଦନହାରି, ଦ୍ଵାଦଶରେ ଶ୍ରୀରାଜ ପ୍ରସାଦ ହାରି, ଘୋଡ଼ାପ୍ରଣାରେ ନେତ୍ରୋତ୍ସବ ଓ ନବଲୋଚନ ଦର୍ଶନ ଭାବିନି କରାଯାଏ । ଧର୍ମ ଘୋଡ଼ାପ୍ରଣା ଦିନ ଠାକୁରମାନଙ୍କୁ ଦର୍ଶନ କରାଯାଏ ସ୍ଵଲୋଚ ସିକେ । ଚାତାରେ ଘୋଡ଼ା ମାସ ଶୁକ୍ଳଭା ଦ୍ଵିତୀୟାରେ ମହାପ୍ରଭୁଙ୍କ ଶୁଣ ସୁଚ୍ଚିତା ମାତ୍ରା ଭାବେ ଘୋଡ଼ାପ୍ରଣା ଦୁର୍ଗ । ସେବାପ୍ରଣା ପ୍ରମାଣରେ ଦିକ୍ଷାପାଠମାନେ ମହାପ୍ରଭୁଙ୍କୁ ନିଜର ଘୋଡ଼ାମାଲ୍ ସୁଜନ ଭାବେ ପୋକାକରା ଥାନ୍ତି । ସେବାପ୍ରଣାରେ ଉତ୍ତମ ଭରେ ନେତ୍ରୋତ୍ସବ ଦିଆଯାଏ । ସେବାପ୍ରଣାରେ ଘୋଡ଼ା ମହାପ୍ରଭୁ ଉପାଳାପାରେ ଭାବେ ଘୋଡ଼ାପ୍ରଣା ଦିଆଯାଏ ।

ଶ୍ରୀ ଶୁକ୍ତିତା :-

ଧ୍ୟାନାତ୍ତ ମାତ୍ର ଶୁକ୍ଳତା ଦ୍ୱିତୀୟା ଦିନ ମହାଗ୍ରହଣେ ଶ୍ରୀ ଶୁକ୍ତିତା ମହୋତ୍ସବ
 ବା ଉପନାତ୍ତା ଆଳିନ କରାଯାଏ । ଚନ୍ଦ୍ର ଉପନାତ୍ତା ନିମନ୍ତେ ବିକାଶ ରଥର ନିର୍ମାଣ କର୍ମ
 କୋଣାର୍କ ମାତ୍ର ଶୁକ୍ଳତା ଦ୍ୱିତୀୟା ବା ଅଲିଲ୍ ଦ୍ୱିତୀୟା ଠାରୁ ଧ୍ୟାନେ ହୋଇଥାଏ । ଉପ
 ନାତ୍ତାଦିନ ଠାକୁରମାନେ ଯାଦି ଉପକୃଷ୍ଟ ହୋଇ ପ୍ରଥମେ ସୁଦର୍ଶନ ଡାକିଲେ ବିଳମ୍ବେ,
 ସୁଦ୍ରା ଓ ଜଗନ୍ନାଥ ରଥକୁ ଶିଳେ କରନ୍ତି । ଗଜପତି ମହାରାଜ ଛୋଟାଉଦ୍ୱାରା କାର୍ଯ୍ୟ
 ଶାନ୍ତିବା ଉପେ ପ୍ରଥମେ ବିଳମ୍ବେ ଡାକିଲେ ସୁଦ୍ରା ଓ ଜଗନ୍ନାଥଙ୍କର ଉପକୃଷ୍ଟ ଶାନ୍ତି ଶାନ୍ତି
 ଶୁକ୍ତିତା ଉପକୃଷ୍ଟ ନିଆଯାଏ । ମହାଗ୍ରହଣ ଶୁକ୍ଳ ନବମୀ ଆଳିନ ଶୁକ୍ତିତା ଉପେ ଉପ ଦଳମୀଦଳ
 ବାଦୁଡା ଶିଳେ କରନ୍ତି । ଶୁକ୍ତିତା ଉପେ ଠାକୁରମାନେ ଧୂବା ପରାନ୍ତରେ ଧ୍ୟାନାତ୍ତ ମାତ୍ର ଶୁକ୍ଳ
 ଉପକୃଷ୍ଟ 'ଦେବା ଉପମା' । ପରମ୍ପରା ଠାରୁ ନବମୀ ଆଳିନ ଧ୍ୟାନ ମତ୍ତ ଉପାସ, ନବମୀଦଳ
 ପରମ୍ପରାଦର୍ଶନ ଧ୍ୟାନାତ୍ତ ହୁଏ । ଦଳମୀ ଦିନ ଠାକୁରମାନେ ଉପକୃଷ୍ଟ ଶିଳେ କରନ୍ତି ଉପରେ ଶ୍ରୀ
 ମନ୍ଦିରକୁ ଦେଖନ୍ତି । ଉପକୃଷ୍ଟ ବାଦୁଡା ଲାତ୍ତା କୁଦାଯାଏ । ଚନ୍ଦ୍ରଦିନ ଜଗନ୍ନାଥଙ୍କ ରଥ ଶ୍ରୀ
 ନିଆର ଆଖରେ ଉପକୃଷ୍ଟେ ଉପକୃଷ୍ଟ ନାଗାଲକ୍ଷ ହେଉ ଥୁଏ ।

ଶାନ୍ତି ଚକାଦିତ୍ୟ :-

ଧ୍ୟାନାତ୍ତ ଶୁକ୍ଳ ଚକାଦିତ୍ୟ ଦିନ ରଥ ଉପରେ ସୁନାବିଜା ଥୁଏ । ଠାକୁରଙ୍କ
 ଉପେ ଧ୍ୟାନାତ୍ତା ହୋଇ ଓ ଶାନ୍ତି ନିମନ୍ତେ ମଧ୍ୟ ଥୁଏ । ଠାକୁରଙ୍କର ଶାନ୍ତି ନିମନ୍ତେ ନିମନ୍ତେ
 ଠାକୁରମାନେ ଉପକୃଷ୍ଟ ଶିଳେ ହୋଇ ଉପକୃଷ୍ଟ ପରମ୍ପରାକୁ ଶିଳେ କରନ୍ତି । ଉପକୃଷ୍ଟ ନାଗାଲକ୍ଷ
 ବିଶେଷ ଓ ଉପକୃଷ୍ଟାଳି କିଣା ନିମନ୍ତେ ମଧ୍ୟ ଥୁଏ । ଦ୍ୱାଦଶୀ ଶୁକ୍ଳ ଶାନ୍ତି ଦ୍ୱାଦଶୀ
 ଉପେ ନାହିଁ । ଚନ୍ଦ୍ର ଦିନ ଶୁକ୍ଳଙ୍କର ଶାନ୍ତି ନିମନ୍ତେ ଥୁଏ ।

ଦିଗ୍‌ଗାମ୍ଭୀ :-

ଶ୍ରୀକୋଣାର୍କ ମାତ୍ର ମହାଗ୍ରହଣ ବା କର୍ମ ମହାଗ୍ରହଣ ଦିନ ମହାଗ୍ରହଣେ ଦିଗ୍‌ଗାମ୍ଭୀ ନାତ୍ତା
 ଆଳିନ ଥୁଏ । ସୁଦର୍ଶନ ଉପକୃଷ୍ଟର ଉପକୃଷ୍ଟେ ଚନ୍ଦ୍ରନାତ୍ତା ଆଳିନ ହୋଇ ଉପକୃଷ୍ଟ ଉପେ ଧ୍ୟାନାତ୍ତ
 ଥୁଏ । ବିଶେଷ ନେତ୍ରପାଦ୍ମ ସହ ଦିଗ୍‌ଗାମ୍ଭୀ ମାତ୍ର ସୁଦର୍ଶନ ଉପେ ମହାଗ୍ରହଣେ ଉପକୃଷ୍ଟ
 କରାଯାଏ । କେବଳି ହେଉଛି ନିମ୍ନେ ଉପକୃଷ୍ଟ ଦିନ ଉପେ ମଧ୍ୟାହ୍ନ ଧ୍ୟାନ ଉପେ ବିମବାଳିମାନଙ୍କୁ ବିଳି
 କରାଯାଏ ।

ଚିତାକାଶି ସେବାକାଣ୍ଡ:-

ଶ୍ରୀକୃଷ୍ଣ ମାତ୍ର ସେବାକାଣ୍ଡ ୧୩ ମଧ୍ୟାହ୍ନକୁ ଚିତାକାଶି ନୀତି ଚାଳନ କରାଯାଏ । ଜ୍ୟେଷ୍ଠମାସ ଭୂକ୍ତିବା ଦେବସ୍ନାନ ଭୂକ୍ତିମା ଦିନ ଶ୍ରୀଜଗନ୍ନାଥଙ୍କୁ ଦ୍ୱିତୀଚିତା, ବିଲହପ୍ରକ୍ତକୁ ନୀଳାଚିତା, ଓ ସୁଭଦ୍ରାଙ୍କୁ ମାଣିକ୍ୟ ଚିତା ବାଦାଏ କରାଯାଏ । ତୃତୀୟ ଉତ୍ତରୀ ଉପାୟକାରୀ । ଚନ୍ଦ୍ରଦିନ ମଧ୍ୟାହ୍ନ ପୂର୍ବ ଭୂକ୍ତି ଚାକ୍ଷୁରଙ୍କ ଚିତାକୁ ବିଧିବଦ୍ଧିକ ଭିକ୍ଷାକାରୀଙ୍କୁ ଚନ୍ଦ୍ର ଚିତାକାଶି ସେବାକାଣ୍ଡ କରାଯାଏ ।

ଦୀର୍ଘଦୂର୍ଗ ବିଧି:-

ଶ୍ରୀକୃଷ୍ଣ ମାତ୍ର ଶୁକ୍ଳପକ୍ଷ ନବମୀଦିନ ମଧ୍ୟାହ୍ନ ପୂର୍ବ ଉତ୍ତରୀ ଭାଗ ଦୂର୍ଗ ସାଧନା ଲେଖି ବିଭବୋଳିରେ ମାର୍ଜଣୀ, ଧୂଳି, ଉଷୁ ଓ ଦୁଗ୍ଧ ସାଦି ଧୋଇବାକୁ ବିଧି କରାଯାଏ ।

ବୃକ୍ଷାଳାପ୍ତ:-

ଶ୍ରୀକୃଷ୍ଣମାତ୍ର ଶୁକ୍ଳ ଦଶମୀଦିନ ତୃତୀୟା ଦିନ ଶ୍ରୀମନ୍ଦିରରେ ବୃକ୍ଷାଳାପ୍ତ କରାଯାଏ । ମଧ୍ୟାହ୍ନ ପୂର୍ବ ଉତ୍ତରୀ ଦୁର୍ଗମଣ୍ଡପ ଉପରେ ନିର୍ଦ୍ଦିଷ୍ଟ ବୃକ୍ଷାଳାପ୍ତ ମନ୍ଦିର ମୋଡ଼ନ କରାଯାଏ ଓ ସୁଭଦ୍ରାଙ୍କୁ ମହାଜନମାନେ ବିଧି କରାଯାଏ । ଶୀତଳ ଦୋହ କରାଯାଏ । ମନ୍ଦିର ଭିତରେ ଚନ୍ଦନ ଭାଗି ସାଗୁରା ଉତ୍ତରୀ ମନ୍ଦିରମୋଡ଼ନକୁ ଦଳିତା ଭାଗୁକୁ ଓ ଭିକ୍ଷା, ସୁଭଦ୍ରାଙ୍କୁ ସିନ୍ଦୂରାଣ ବିଧି କରାଯାଏ । ବୃକ୍ଷାଳାପ୍ତକୁ 'ବୃକ୍ଷାଳାପ୍ତ' କୁହାଯାଏ । ବିଲହପ୍ରକ୍ତ ଉପାୟକାରୀ ଚନ୍ଦ୍ର ଦିନ ଚାଳନ କରାଯାଏ ।

ବାହୁଦେବୀ ଭାଗି:-

ବାହୁଦେବୀ ଭାଗି:- ବାହୁଦେବୀ ଭାଗି ଉତ୍ତରୀ ଉପାୟକାରୀ ଚନ୍ଦ୍ରଦିନ ଚାଳନ କରାଯାଏ । ସ୍ନାନଲାଭା ସମୟରେ ଚାକ୍ଷୁରଙ୍କୁ ବାହୁଦେବୀ ଭାଗି କରାଯାଏ । ଓ ନୀତି ବିଧି ବଦ୍ଧିକ ଭାଗି କରାଯାଏ । ଚନ୍ଦ୍ର ବାହୁଦେବୀ ଭାଗି କର୍ମ ବାହୁଦେବୀ ବିଧିକାରୀ କରାଯାଏ ।

ଶାଧାବାଣୀର ଲକ୍ଷଣ:-

ଶାଧାବାଣୀର କେବଳ ଦଶଦ୍ୱାରା ଉଚ୍ଚର ଧରଣର ଶୁଦ୍ଧ ଧରଣର
ସମ୍ପର୍କ ଧାରଣ କରନ୍ତି । ଓ ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର
ନିର୍ଦ୍ଦେଶ ଦେଖ , କାର୍ଯ୍ୟକ୍ରମର ଓ କାର୍ଯ୍ୟକ୍ରମ , ଧରଣର ଧରଣର
କାର୍ଯ୍ୟକ୍ରମର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର
ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର
ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର

ଦ୍ୱିତୀୟ ଲକ୍ଷଣ:-

ଦ୍ୱିତୀୟ ଲକ୍ଷଣର କାର୍ଯ୍ୟକ୍ରମ ଧରଣର ଧରଣର ଧରଣର
ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର

ତୃତୀୟ ଲକ୍ଷଣ:-

ତୃତୀୟ ଲକ୍ଷଣର କାର୍ଯ୍ୟକ୍ରମ ଧରଣର ଧରଣର ଧରଣର
ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର

ଚତୁର୍ଥ ଲକ୍ଷଣ:-

ଚତୁର୍ଥ ଲକ୍ଷଣର କାର୍ଯ୍ୟକ୍ରମ ଧରଣର ଧରଣର ଧରଣର
ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର ଧରଣର

ଉଦ୍ଦିଳି ହୋଗ :-

ଅନ୍ତଃ ପ୍ରକାଶିତ ଚନ୍ଦ୍ର ମଙ୍ଗଳ ପ୍ରକାଶିତ ସ୍ୱାର୍ଥକ୍ଷେତ୍ର ଯୋଗମାତ୍ରରେ ଶୁଣିଗଣନାଧିକ
 ମନ୍ଦିରରେ ଉଦ୍ଦିଳି ହୋଗ ନମିତି ଦୁଃଖ । ଧର୍ମ ମାତ୍ରରେ ଅନ୍ତଃସ୍ୱାତ୍ତ ଚନ୍ଦ୍ରରୁ ହୋଗ କରାଯାଏ
 ଦୋଷିକ ବିକଳିତ ହୁଏ ଉଦ୍ଦିଳି ହୋଗ ଦୁଃଖ । କିମ୍ବଦନ୍ତୀ ଧର୍ମ ଧର୍ମ ପ୍ରକାଶରେ ଲକ୍ଷ୍ମୀ ନିଜ
 ଉଦ୍ଦିଳିତରୁ ଶମନ କରିଥାନ୍ତୁ ଜନନୀ ଲକ୍ଷ୍ମୀଦା ନିଜର ଧୂଳିକୁ ଶେଷରେ ଧାରଣାକୁ
 ଦିଅନ୍ତୁ । ଧର୍ମ ଉଦ୍ଦିଳି ହୋଗ ରୁଦ୍ଧେ କରୁଥ । ଧର୍ମ ଉଦ୍ଦିଳି ହୋଗରେ ବିଧି, ପତି,
 ପିତା, କାକିଣୀ, ସୋମାଳୁ, ସାହିତ୍ୟ, ଲଢ଼, ଶକା, ଶକ୍ତିଶା, ମହା, ଶୁକ୍ଳ, ପୁତ୍ରାଦି, କର୍ତ୍ତବ୍ୟ
 ଶେଷରେନିଦା ଧର୍ମ ଦିନ ହୋଗ କରାଯାଏ । ଧର୍ମ ପ୍ରକାଶରେ ଶୁଣି ହୋଗ ମହତ୍ତ୍ୱ ପୂଜା
 ପ୍ରକାଶରୁ ଚାହୁଁଥିବୁ ଧନ ଉଦ୍ଦିଳି ନମିତି ଦୁଃଖ । ମଙ୍ଗଳ ପ୍ରକାଶିତ ଉଦ୍ଦିଳି ନିକାଳ ଓ ଧୂଳି
 ମୋକ୍ଷାଦା ଦୁଃଖ । ମଙ୍ଗଳ ପ୍ରକାଶିତ ଧନ ନିକାଳ କ୍ଷେତ୍ରା ପ୍ରକାଶ ଉଦ୍ଦିଳି ଚାହୁଁଥିବୁ ମଙ୍ଗଳ ଚାହୁଁ
 ହୋଗ କରାଯାଏ । ଧର୍ମ ଦିନ ଉଦ୍ଦିଳି ହୋଗ ପ୍ରକାଶ ଦୁଃଖ ।

ପୁରାଣାଦିତୋକ :-

ଯୋଗମାତ୍ର ଉଦ୍ଦିଳିମା ଧନ ମହାତ୍ତ୍ୱରୁକ୍ତ ପୁରାଣାଦିତୋକ ନମିତି ଦୁଃଖ । ଧର୍ମ ପୂର୍ବ
 ଧର୍ମାଦିନୀ ଧନ-ମନ୍ଦିର ଉଦ୍ଦିଳିତ ହୁଏ ମହତ୍ତ୍ୱ ଧର୍ମରେ ଧର୍ମରାଜତା ଭୂଜା କରି-
 ଥାଆନ୍ତି । ଦିନିକା ଭାବ ହୋଗ ପ୍ରକାଶ ଦେବା ଭାବେ ଉଦ୍ଦିଳିତ ହିତର ପ୍ରକାଶନରୁ
 ବିକଳିତରୁ ଧର୍ମାଦିନୀ କିନ୍ତୁ ଭାବିକରେ ଲକ୍ଷ୍ମୀକ ମନ୍ଦିରକୁ ବାହାର ଧର୍ମତୋକ
 ନିମନ୍ତେ ବିକଳିତରୁ ।

ବିଷୟ ଅଧିକାର :-

ମାତ୍ରାମାତ୍ର ଧର୍ମ ଅଧିକାର ରୁଦ୍ଧେ ଭାବିକ । ଧର୍ମ ଧନ ବାଗଦେବୀକୁ ଭୂଜା
 କରାଗଲେ ମଧ୍ୟ ଶୁଣି ମନ୍ଦିରରେ ଭାବିକରୁକ୍ତ ବାଦରେ ମୁକ୍ତିରୁଥ ଓ ଲକ୍ଷ୍ମୀକ
 ବାଦରେ ପ୍ରକାଶ ନିଲୋଗ ହିତର ଧର୍ମାଦି ଜରୁରୀମାନଙ୍କରେ ଭାବେ ଧର୍ମକି ।
 ଧର୍ମ ଚାହୁଁ ଶୁଣିକ ହୋଗ ଓ ଭାବି ଦୁଃଖ । ହୋଗ ଭାବେ ବିକଳି ଧର୍ମ ନିମନ୍ତେ
 ଜଗନ୍ନାଥ ବିକଳି ମହତ୍ତ୍ୱ ବିକଳି ଧର୍ମାଦିନୀ ଧର୍ମାଦି । ପ୍ରକାଶ ଧର୍ମ ପ୍ରକାଶ ଭାବେ
 ପ୍ରକାଶରୁକ୍ତ ମନ୍ଦିରରେ ଭାବି ଭୂଜା ଦୁଃଖ ।

ଶକ୍ତିକ୍ଷମତା ବିକାଶ:-

ମାତାମାତ୍ର ଭୂମିକା ମଧ୍ୟକୁ ଧ୍ୟାନ ଦେଇ ଚାହୁଁଥିବାରୁ ଶକ୍ତି କ୍ଷମତା ବିକାଶ ହୁଏ । ଧ୍ୟାନ ବିକାଶ ହେତୁ ଗୋଟିଏ ଦିନ ମଧ୍ୟରୁ ଦିନ ମଧ୍ୟ ଧ୍ୟାନ ହୁଏ । ଧ୍ୟାନ ବିକାଶ ହେତୁ ଶକ୍ତିକ୍ଷମତା ବିକାଶ କରାଯାଏ ।

ଦୋଳିଲାଭ:-

ଦୋଳିଲାଭ ମାତ୍ର ଶୁଦ୍ଧ ଦୋଳିଲାଭକୁ ଭୂମିକା ଭାବରେ ଦୋଳିଲାଭକୁ ବିଧାନ ଶୁଣି ମନରେ ଭାବିବୁ ଦୁଃଖ । ଦୋଳିଲାଭ ମଧ୍ୟକୁ ଧ୍ୟାନ ଦେଇ ଶକ୍ତିକ୍ଷମତା ବିକାଶ ହୁଏ ।

ଶାନ୍ତିଲାଭ:-

ଶାନ୍ତିଲାଭ ଶୁଦ୍ଧ ଦୋଳିଲାଭକୁ ଶୁଣି ମନରେ ଶାନ୍ତିଲାଭକୁ ବିଧାନ ଭାବେ ଦୋଳିଲାଭକୁ ବିଧାନ ହୁଏ । ଶାନ୍ତିଲାଭ ମଧ୍ୟକୁ ଧ୍ୟାନ ଦେଇ ଶକ୍ତିକ୍ଷମତା ବିକାଶ ହୁଏ ।

ଶ୍ରୀଜଗନ୍ନାଥ ଗୋଲ୍ଲୋଚନ ଧାମକୁ ଶ୍ରୀମଦ୍‌ଗୁରୁଗୋବିନ୍ଦଧାମର ଧ୍ୟାନୋଦ୍ଧୃତି କରି ଜଗନ୍ନାଥ ଦାସ
ପ୍ରମୁଖ ଭକ୍ତଙ୍କ ସହ ସଂସ୍କୃତି କବିତାମାନ ଉତ୍ତମ କରିଥିଲେ । ଶ୍ରୀକୃଷ୍ଣଙ୍କୁ ଦେବାଧିକାରୀ
ଭାବେ ତାଙ୍କର ଧ୍ୟାନୋଦ୍ଧୃତି ନିହିତସ୍ତୁ ଦାମ୍ଭସ୍ତୁ ଉଭୟ ନ୍ୟାସନୀର ଧ୍ୟାନ କରି ବିଦ୍ଵାନ୍‌ମାନ
କରିଛନ୍ତି : ତାହା କୃତାନ୍ତ ସମ୍ପର୍କ ଦ୍ଵାରା ଧ୍ୟାନେ ବର୍ଣ୍ଣିତ ହେଉଛି ।

" କେନ୍ଦ୍ରୀୟ ଦାମ୍ଭ ସୁଦେହୁଁ । ବିଜୟ ପ୍ରଭୁ ଦେହୁଁ ।

ଦ୍ଵାଜା ତା ଧ୍ୟାନୋଦ୍ଧୃତି ଧ୍ୟାନେ । ପ୍ରାସାଦି ହିତରେ ଧ୍ୟାନେ ।
ଧ୍ୟାନେ ଗୋଲ୍ଲୋଚନ ଧ୍ୟାନେ । କେନ୍ଦ୍ରୀୟ ଧ୍ୟାନେ ନ୍ୟାସନୀ ।
ଧ୍ୟାନେ ଚନ୍ଦ୍ରଧାମ୍ଭସୁଦେହୁଁ । କେନ୍ଦ୍ରୀୟ ଦାମ୍ଭ ସୁଦେହୁଁ ।
ଧ୍ୟାନେ ନୃଦାସି ଧ୍ୟାନେ । ମନରେ ଦ୍ୟାୟକ୍ତ କାନ୍ଦେ ।
ଧ୍ୟାନେ ନ୍ୟାସନୀ ବିଦ୍ଵାନ୍‌ମାନ । ଧ୍ୟାନେ ନିଗୋପ ଧ୍ୟାନେ ।
ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ । ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ ।
ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ । ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ ।
ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ । ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ ।

(ଦାମ୍ଭ ସୁଦେହୁଁ ଧ୍ୟାନେ)

ଧ୍ୟାନେ 'ଧ୍ୟାନେ' ଧ୍ୟାନେ କବି ଜଗନ୍ନାଥ ଦାସ ଶ୍ରୀଜଗନ୍ନାଥଙ୍କୁ ପ୍ରତ୍ୟେକ ସମ୍ପର୍କ ଦ୍ଵାରା
ଧ୍ୟାନେ କରିଛନ୍ତି ।

" ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ .
ଧ୍ୟାନେ ଧ୍ୟାନେ ଧ୍ୟାନେ । "

PROJECT REPORT ON

DEPARTMENT OF ODIA

PATTAMUNDAI COLLEGE, PATTAMUNDAI

SESSION 2021-22

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18			
19			
20			
21			

PATTAMUNDAI COLLEGE
PATTAMUNDAI

DEPARTMENT OF PHYSICS



PROJECT
ON

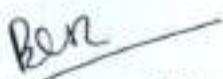
"FUNDEMENTAL FORCES AND
ELEMENTARY PARTICLES"

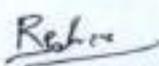
PREPARED BY 3RD YEAR STUDENTS

AND

SUPERVISED BY -: Baikunth Charan Roul

March-2022


Signature of the
Supervisor


signature of
H.O.D. Physics

REPORT

A project on "FUNDAMENTAL FORCES AND ELEMENTARY PARTICLES" was prepared by students of Department of Physics during the month of March 2022. Two members of student participated in the project work. They collected several materials on the concerned topic from different Libraries and other studious Places. The department faculties co-operated them in all these works and this project is original.

Radhika
H. O. P. Physics
PH.D., Physics
Pattamundai College

[Signature]
Principal
Pattamundai College

PROJECT ON : FUNDAMENTAL FORCES AND ELEMENTARY

PARTICLES

DEPARTMENT OF PHYSICS,

PATTAMUNDAI COLLEGE, PATTAMUNDAI.

SESSION 2021-2022

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- Introduction
- History of fundamental forces
- Overview of the fundamental interaction
- Fundamental interactions
- Elementary particle
- Reference

Introduction

The theories and discoveries of thousands of physicists since the 1930s have resulted in a remarkable insight into the fundamental structure of matter: everything in the universe is found to be made from a few basic building blocks called fundamental particles, governed by four fundamental forces. In physics, the fundamental interactions, also known as fundamental forces. There are four fundamental interactions known to exist: the gravitational and electromagnetic interactions, which produce significant long-range forces whose effects can be seen directly in everyday life, and the strong and weak interactions, which produce forces at minuscule, subatomic distances and govern nuclear interactions. Some scientists hypothesize that a fifth force might exist, but these hypotheses remain speculative. Each of the known fundamental interactions can be described mathematically as a field. The gravitational force is attributed to the curvature of spacetime, described by Einstein's general theory of relativity. The other three are discrete quantum fields, and their interactions are mediated by elementary particles described by the Standard Model of particle physics. Many theoretical physicists believe these fundamental forces to be related and to become unified into a single force at very high energies on a minuscule scale, the Planck scale, but particle accelerators cannot produce the enormous energies required to experimentally probe this.

The weak and electromagnetic forces have already been unified with the electroweak theory of Sheldon Glashow, Abdus Salam, and Steven Weinberg, for which they received the 1979 Nobel Prize in physics. Some physicists seek to unite the electroweak and strong fields within what is called a Grand Unified Theory (GUT). An even bigger challenge is to find a way to quantize the gravitational field, resulting in a theory of quantum gravity (QG) which would unite gravity in a common theoretical framework with the other three forces. Some theories, notably string theory, seek both QG and GUT within one framework, unifying all four fundamental interactions along with mass generation within a theory of everything (ToE).

History Of Fundamental Force:

1. Classical History: In his 1687 theory, Isaac Newton postulated space as an infinite and unalterable physical structure existing before, within, and around all objects while their states and relations unfold at a constant pace everywhere, thus absolute space and time. Newton inferred that matter exhibits an attractive force. His law of universal gravitation implied there to be instant interaction among all objects. As conventionally interpreted, Newton's theory of motion modelled a central force without a communicating medium. Conversely In 1873, James Clerk Maxwell unified electricity and magnetism as effects of an electromagnetic field whose consequence was light, travelling at constant speed in a vacuum. If his electromagnetic field theory held true in all inertial frames of reference, this would contradict Newton's theory of motion, which relied on Galilean relativity.

2. The Standard Model: The Standard Model of particle physics was developed throughout the latter half of the 20th century. In the Standard Model, the electromagnetic, strong, and weak interactions associate with elementary particles, whose behaviours are modelled in quantum mechanics (QM). For predictive success with QM's probabilistic outcomes, particle physics conventionally models QM events across a field set to special relativity, altogether relativistic quantum field theory (QFT). Force particles, called gauge bosons—force carriers or messenger particles of underlying fields—interact with matter particles, called fermions. Everyday matter is atoms, composed

Standard Model of Elementary Particles

			three generations of matter (fermions)			interactions / force carriers (bosons)	
			I	II	III		
QUARKS	mass		$\sim 2.2 \text{ MeV}/c^2$	$\sim 1.28 \text{ GeV}/c^2$	$\sim 173.1 \text{ GeV}/c^2$	0	$\sim 125.37 \text{ GeV}/c^2$
	charge		$\frac{2}{3}$	$\frac{2}{3}$	$\frac{2}{3}$	0	0
	spin		$\frac{1}{2}$	$\frac{1}{2}$	$\frac{1}{2}$	1	0
			u up	c charm	t top	g gluon	H higgs
			$\sim 4.7 \text{ MeV}/c^2$	$\sim 95 \text{ MeV}/c^2$	$\sim 4.18 \text{ GeV}/c^2$	0	
			$\frac{1}{3}$	$\frac{1}{3}$	$\frac{1}{3}$	0	
			$\frac{1}{2}$	$\frac{1}{2}$	$\frac{1}{2}$	1	
			d down	s strange	b bottom	γ photon	
			$\sim 0.511 \text{ MeV}/c^2$	$\sim 105.66 \text{ MeV}/c^2$	$\sim 1.777 \text{ GeV}/c^2$	0	$\sim 91.18 \text{ GeV}/c^2$
			-1	-1	-1	0	0
			$\frac{1}{2}$	$\frac{1}{2}$	$\frac{1}{2}$	1	1
			e electron	μ muon	τ tau	Z Z boson	
LEPTONS			$\sim 1.2 \text{ eV}/c^2$	$\sim 0.17 \text{ MeV}/c^2$	$\sim 18.2 \text{ MeV}/c^2$	0	$\sim 80.39 \text{ GeV}/c^2$
			0	0	0	1	1
			$\frac{1}{2}$	$\frac{1}{2}$	$\frac{1}{2}$	1	1
			ν_e electron neutrino	ν_μ muon neutrino	ν_τ tau neutrino	W W boson	

GAUGE BOSONS
VECTOR BOSONS

SCALAR BOSONS

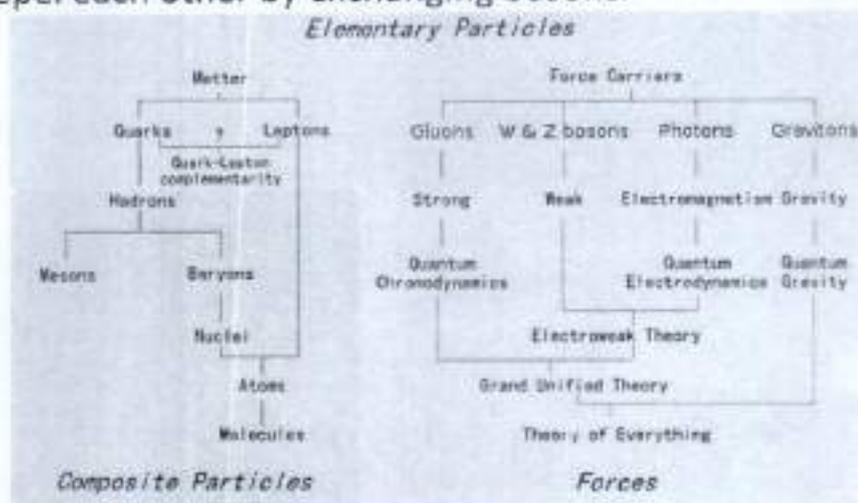
of three fermion types: up-quarks and down-quarks constituting, as well as electrons orbiting, the atom's nucleus. The force carriers of the weak interaction are the massive W and Z bosons.

Overview of the fundamental interactions

In the conceptual model of fundamental interactions, matter consists of fermions, which carry properties called charges and spin $\pm 1/2$ (intrinsic angular momentum $\pm \hbar/2$, where \hbar is the reduced Planck constant). They attract or repel each other by exchanging bosons.

The exchange of bosons always carries energy and momentum between the fermions, thereby changing their speed and direction. The exchange may also transport a charge between the fermions, changing the charges of the fermions in the process (e.g., turn

them from one type of fermion to another). "Since bosons carry one unit of angular momentum, the fermion's spin direction will flip from $+1/2$ to $-1/2$ (or vice versa) during such an exchange (in units of the reduced Planck's constant). Since such interactions result in a change in momentum, they can give rise to classical Newtonian forces. In quantum mechanics, physicists often use the terms "force" and "interaction" interchangeably; for example, the weak interaction is sometimes referred to as the "weak force"



Interaction	Current theory	Mediators	Relative strength ^[20]	Long-distance behavior	Range (m) ^[21]
Weak	Electroweak theory (EWT)	W and Z bosons	10^{25}	$\frac{1}{r} e^{-m_{W,Z} r}$	10^{-18}
Strong	Quantum chromodynamics (QCD)	gluons	10^{38}	$\sim r$ (Color confinement, see discussion below)	10^{-15}
Electromagnetic	Quantum electrodynamics (QED)	photons	10^{36}	$\frac{1}{r}$	∞
Gravitation	General relativity (GR)	gravitons (hypothetical)	1	$\frac{1}{r}$	∞

The Fundamental Interactions

1. Gravity

Gravitation is by far the weakest of the four interactions at the atomic scale, where electromagnetic interactions dominate. Gravitation is the most important of the four fundamental forces for astronomical objects over astronomical distances for two reasons. First, gravitation has an infinite effective range, like electromagnetism but unlike the strong and weak interactions. Second, gravity always attracts and never repels; in contrast, astronomical bodies tend toward a near-neutral net electric charge, such that the attraction to one type of charge and the repulsion from the opposite charge mostly cancel each other out. [22] Even though electromagnetism is far stronger than gravitation, electrostatic attraction is not relevant for large celestial bodies, such as planets, stars, and galaxies, simply because such bodies contain equal numbers of protons and electrons and so have a net electric charge of zero. Nothing "cancels" gravity, since it is only attractive, unlike electric forces which can be attractive or repulsive. On the other hand, all objects having mass are subject to the gravitational force, which only attracts. Therefore, only gravitation matters on the large-scale structure of the universe. The long range of gravitation makes it responsible for such large-scale phenomena as the structure of galaxies and black holes and it retards the expansion of the universe. Gravitation also explains astronomical phenomena on more modest scales, such as planetary orbits, as well as everyday experience: objects fall; heavy objects act as if they were glued to the ground, and animals can only jump so high. Gravitation was the first interaction to be described mathematically. In ancient times, Aristotle hypothesized that objects of different masses fall at different rates. During the Scientific Revolution, Galileo Galilei experimentally determined that this hypothesis was wrong under certain circumstances — neglecting the friction due to air resistance and buoyancy forces if an atmosphere is present (e.g. the case of a dropped air-filled balloon vs a water-filled balloon), all objects accelerate toward the

Earth at the same rate. Isaac Newton's law of Universal Gravitation (1687) was a good approximation of the behaviour of gravitation. Our present-day understanding of gravitation stems from Einstein's General Theory of Relativity of 1915, a more accurate (especially for cosmological masses and distances) description of gravitation in terms of the geometry of spacetime. Merging general relativity and quantum mechanics (or quantum field theory) into a more general theory of quantum gravity is an area of active research. It is hypothesized that gravitation is mediated by a massless spin-2 particle called the graviton. Although general relativity has been experimentally confirmed (at least for weak fields, i.e. not black holes) on all but the smallest scales, there are Alternatives to general relativity. These theories must reduce to general relativity in some limit, and the focus of observational work is to establish limits on what deviations from general relativity are possible. Proposed extra dimensions could explain why the gravity force is so weak.

2. Electromagnetic Interaction

Electromagnetism is the force that acts between electrically charged particles. This phenomenon includes the electrostatic force acting between charged particles at rest, and the combined effect of electric and magnetic forces acting between charged particles moving relative to each other. Electromagnetism has an infinite range like gravity, but is vastly stronger than it, and therefore describes a number of macroscopic phenomena of everyday experience such as friction, rainbows, lightning, and all human-made devices using electric current, such as television, lasers, and computers. Electromagnetism fundamentally determines all macroscopic, and many atomic-level, properties of the chemical elements, including all chemical bonding. This force is many times larger than the weight of the planet Earth. The atomic nuclei in one jug also repel those in the other with the same force. However, these repulsive forces are canceled by the attraction of the electrons in jug A with the nuclei in jug B and the attraction of

the nuclei in jug A with the electrons in jug B, resulting in no net force. Electromagnetic forces are tremendously stronger than gravity but cancel out so that for large bodies gravity dominates. Electrical and magnetic phenomena have been observed since ancient times, but it was only in the 19th century James Clerk Maxwell discovered that electricity and magnetism are two aspects of the same fundamental interaction. By 1864, Maxwell's equations had rigorously quantified this unified interaction. Maxwell's theory, restated using vector calculus, is the classical theory of electromagnetism, suitable for most technological purposes. The constant speed of light in a vacuum (customarily described with a lowercase letter "c") can be derived from Maxwell's equations, which are consistent with the theory of special relativity. Albert Einstein's 1905 theory of special relativity, however, which follows from the observation that the speed of light is constant Electroweak interaction Electromagnetism no matter how fast the observer is moving, showed that the theoretical result implied by Maxwell's equations has profound implications far beyond electromagnetism on the very nature of time and space.

3. Weak Interaction

The weak interaction or weak nuclear force is responsible for some nuclear phenomena such as beta decay. Electromagnetism and the weak force are now understood to be two aspects of a unified electroweak interaction — this discovery was the first step toward the unified theory known as the Standard Model. In the theory of the electroweak interaction, the carriers of the weak force are the massive gauge bosons called the W and Z bosons. The weak interaction is the only known interaction that does not conserve parity; it is left–right asymmetric. The weak interaction even violates CP symmetry but does conserve CPT.

4. Strong Interaction

The strong interaction, or strong nuclear force, is the most complicated interaction, mainly because of the way it varies with distance. The nuclear force is powerfully attractive between nucleons at distances of about 1 femtometre (fm, or 10^{-15} metres), but it rapidly decreases to insignificance at distances beyond about 2.5 fm. At distances less than 0.7 fm, the nuclear force becomes repulsive. This repulsive component is responsible for the physical size of nuclei, since the nucleons can come no closer than the force allows. After the nucleus was discovered in 1908, it was clear that a new force, today known as the nuclear force, was needed to overcome the electrostatic repulsion, a manifestation of electromagnetism, of the positively charged protons. Otherwise, the nucleus could not exist. Moreover, the force had to be strong enough to squeeze the protons into a volume whose diameter is about 10^{-15} m, much smaller than that of the entire atom. From the short range of this force, Hideki Yukawa predicted that it was associated with a massive force particle, whose mass is approximately 100 MeV. The 1947 discovery of the pion ushered in the modern era of particle physics. Hundreds of hadrons were discovered from the 1940s to 1960s, and an extremely complicated theory of hadrons as strongly interacting particles was developed.

- The pions were understood to be oscillations of vacuum condensate
- Jun John Sakurai proposed the rho and omega vector bosons to be force carrying particles for approximate symmetries of isospin and hypercharge;
- Geoffrey Chew, Edward K. Burdett and Steven Frautschi grouped the heavier hadrons into families that could be understood as vibrational and rotational excitations of strings.

ELEMENTARY PARTICLES

Elementary Particles Circa 1930. By the 1930's physicists recognized four elementary particles and four fundamental forces (see Table 2). The interactions that the particles take part in are shown after the particle name. Note that only the neutron and proton take part in the strong interaction.² Thus, one might have ventured to say in the 1930's that the number of elementary particles was remarkably few. Furthermore these particles, interacting via the four fundamental forces were the components of all matter in the universe and that all phenomena in the universe could, in principle, be explained in terms of these particles and interactions. However, there were large gaps of knowledge to be filled in this picture before full understanding was achieved. First of all, the "quanta" of the strong interaction needed to be identified

Elementary particles and the fields with which they interact, as viewed in the 1930's. The fields are denoted: S = netic, W = Weak, = Gravitational.	
Elementary	Interacting
Neutron	S, E, W, G
Proton	S, E, W, G
Electron	E, W, G
Photon	E, G

Baryons, Mesons, and Leptons. When, in the late 1940's, what was thought to be these quanta were discovered, it turned out to be only the beginning. Over the years, not only did a complex spectrum of quanta of various masses appear, called "mesons," there also was discovered a spectrum of heavier strongly interacting particles, called "baryons." The "ground state" of this baryon spectrum is the familiar proton, and the first excited state is the neutron. The particles in these two spectra, all of which take part in the strong interaction, are collectively called "hadrons." The study of the properties of these hadrons and the search for what these properties tell about the

nature of the strong interaction, occupies a significant part of what is called "high energy physics." An important step in unraveling the mysteries of hadronic physics is devising intelligent schemes for classifying these large numbers of hadrons.¹ A third spectrum of particles, called "leptons," or "light particles," do not participate in the strong interaction. The members of this class includes the electron, the muon (a heavy version of the electron) and neutrinos corresponding to the electron and the muon.

Intrinsic Properties of the Elementary Particles. The intrinsic properties of the elementary particles are their mass, charge, spin, and magnetic moments. These properties are listed in Table 3 for the elementary particles we will encounter.

Intrinsic Properties of Elementary Particles. Mass in MeV/c², charge in units of e, spin in units of h.

Family	Particle	Symbol	Mass	Charge	Spin
	photon	γ	0	0	1
LEPTONS	electron's neutrino	ν_e	0	0	1/2
	muon's neutrino		0	0	1/2
	tau's neutrino	ν_τ	0	0	1/2
	electron	e^-	0.511	-1	1/2
	muon	μ^-	105.66	-1	1/2
	tau	T^-	1784.2	-1	1/2
	HADRONS:				
mesons	pion	π^0	134.96	0	0
		π^+	139.57	+1	0
		π^-	139.57	-1	0
	Kaon	K^+	493.8	+1	0
		K^-	493.8	-1	0
		K^0	493.8	0	0
	eta	η	548.8	0	0
baryons	proton	p	938.26	+1	1/2
	neutron	n	939.55	0	1/2
	lambda	Λ^0	1115.6	0	1/2
	sigma	Σ^+	1189.4	+1	1/2
		Σ^0	1192.5	0	1/2
		Σ^-	1197.4	-1	1/2
	xi	Ξ^0	1315	0	1/2
		Ξ^-	1321.3	-1	1/2
		omega	ω^-	1673	-1

Pair Production and Annihilation. For every particle listed in Table 3 there is an "antiparticle" with the same mass but opposite charge. An antiparticle is symbolized by the particle symbol with a bar over it e.g. \bar{p} is an antiproton. Exceptions to this nomenclature rule include the chargeless photon and π^0 meson, which are their own antiparticles, and the electron, whose antiparticle is given the special name of "positron" with the symbol e^+ . A particle and its antiparticle may be created spontaneously out of energy in a process called "pair production." To conserve momentum, such a particle-antiparticle pair must have equal and opposite momenta. The energy required for such a process is equal to the rest energy of both particles plus their total kinetic energy. When a particle and an antiparticle combine, they destroy each other in a process called "pair annihilation." The total energy of the pair (rest energy plus kinetic)

converted into two or more photons of equivalent energy. At least two photons must be created to conserve momentum in the process.

Particle Decay. The majority of the particles in Table 3 have finite lifetimes and decay radioactively to some other state or group of particles with a characteristic mean life.¹ Most particles that decay have more than one final state, or "decay mode, available, although frequently one decay mode is dominant. The only particles which appear to be stable against decay are the photon, the electron, both neutrinos (ν_e and ν_m) and the proton.

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PATTAMUNDAI COLLEGE
PATTAMUNDAI

DEPARTMENT OF PHYSICS



PROJECT
ON

"LASER DIODE"

PREPARED BY 3RD YEAR STUDENTS

AND

SUPERVISED BY -: Baikunth Charan Roul

March-2022

B.K.R.

Signature of the
Supervisor

R.S.

signature of
H.O.D. Physics

REPORT

A project on "LASER DIODE" was prepared by students of Department of Physics during the month of March 2022. Two members of student participated in the project work. They collected several materials on the concerned topic from different Libraries and other studious Places. The department faculties co-operated them in all these works and this project is original.

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PROJECT ON : LASER DIODE

DEPARTMENT OF PHYSICS,

PATTAMUNDAI COLLEGE, PATTAMUNDAI.

SESSION 2021-2022

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2. ADVANTAGES & DISADVANTAGES
3. APPLICATION
4. METHODOLOGY
5. RESULTS
6. DISCUSSION
7. CONCLUSION

1. Introduction

Diode lasers are semiconductor devices that use the p-n junction of a semiconductor diode to create light that is coherent and generally of a single wavelength. Due to the small size, low power consumption, and cost-effective production of these devices, diode lasers have become the most common types of lasers in the world, used in a large variety of components and fields, including electronics, communications, and medical practices. The function of diode lasers is dependent on a variety of properties, including the threshold current, slope efficiency, and characteristic temperature.

When investigating the properties of a diode laser, a plot of the detector output vs. forward current, known as an L-I characteristic, can be used to determine the threshold current and the dependence of the diode laser at various temperatures. When the data is plotted, the point at which there is a significant change in detector output is an indication that the device has reached lasing conditions. The current at which this occurs is the threshold current of the laser.

The slope of the L-I characteristic can determine the efficiency of the diode laser once the diode laser has been supplied with a current higher than its threshold current. No device is 100% efficient, with the best diode lasers available able to convert approximately 50% of the electrical input power into laser light.

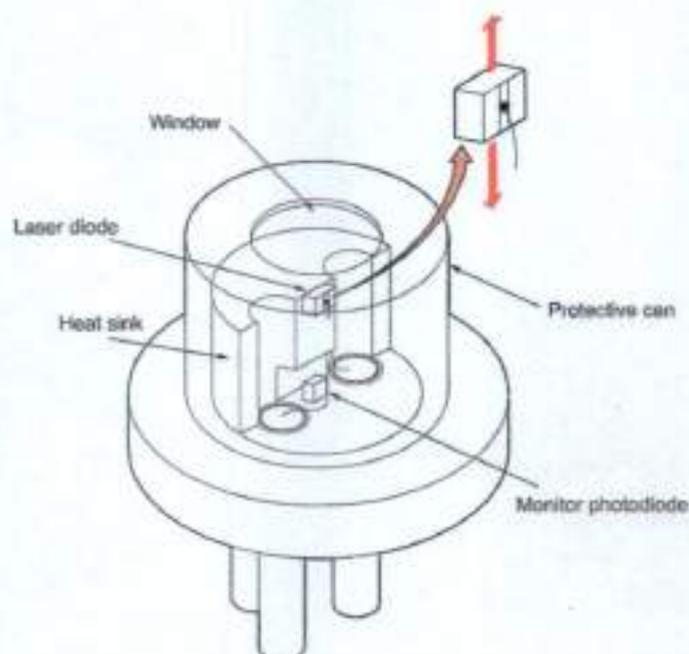
Diode lasers are extremely sensitive to temperature, which can influence their functionality and efficiency. By collecting data and plotting L-I characteristics at multiple temperatures between 5°C and 40°C, this temperature dependence is clearly observable, influencing the value of the threshold current for the diode laser as well as the diode laser's efficiency.

A fundamental property of a diode laser is the characteristic temperature of the device. Every laser device has an independent characteristic temperature value, which represents the diode laser's thermal stability. Diode lasers with higher characteristic temperatures are less susceptible to thermal changes of the device and its surrounding environment, yielding a more dependable and stable laser. The characteristic temperature can be empirically calculated using the relation Eq. 1.

$$I_{th} \propto e^{T/T_0} \quad (1)$$

The characteristic temperature is an important quality for determining whether a diode laser is "good" or not.

The profile of the output laser beam of a laser diode is also of fundamental importance. The cross-sectional power distribution of the beam can be measured to determine the shape of the beam profile. From this information, the divergence of the beam in the parallel and perpendicular to the junction may be determined. The divergence of the laser beam is important for understanding the propagation of the beam through space at extended distances, and why the beam profile takes the Gaussian shape associated with it.



2. Advantages and disadvantages of LASER diode

The terms stand for LASER full form Light Amplification by Stimulated Emission of Radiation. It can produce coherent radiation in the visible or in an infrared spectrum when current passes through it. It can be used in optical fiber systems, compact disk players and also some remote control devices. Here this post gives information about the advantages and disadvantages of LASER diode to know more about it.

Advantages of LASER diode :

- Simple economic design
- It has low power as compared to other types of laser diodes
- Better modulation capability
- The laser diode has a high coupling efficiency
- It can be used at high temperatures
- It gives high optical power
- In this diode cheaper device to produce laser output

- It has a smaller size as compared to other types of laser diodes
- Production of light can be precisely controlled
- Laser diode to transmit optical output powers between the range of about 5 and 10 mW
- Low spectral width (3.5 nm)
- Compact
- It is easily manufactured in arrays
- The delivered system not as expensive as hard tissue laser diode
- Ability to maintain the intrinsic layer characteristics over long time periods

Disadvantages of LASER diode :

- It produces a more divergent laser beam
- They require big and costly optics for a large source of size
- It has a critical heating problem
- High drive current to drive the large laser for pellets
- Expensive
- A speckle pattern appears as two coherent types of light beams to added or subtracts their electric field depending upon their relative phases at the end of the fiber optic device
- Poorly absorb in hard tissue and hydroxyapatite
- Current produces unfavorable thermal characteristics
- Necessitates the use of cooling and power stabilization

3.Applications of Laser Diode :

The following are the applications of laser diode:

- **Consumer electronics:** This includes laser printers, CDs and DVD players, and fiber optic communication.
- **Industrial applications:** When it comes to industrial applications, laser diodes are preferred as it is a source of a high-intensity laser beam and used for cutting, drilling, welding, etc.
- **Medical applications:** Laser diode is used for the elimination of unwanted tissues and tumors and also in dental medication.
- **Scientific instrumentation:** Instruments like spectrometer, range finders, contact-less measurements can be done with the help of laser diodes.
- **The laser diode in telecom:** Laser diodes with 1.3 μm and 1.55 μm bands are used as the main source of light in telecom and as the band changes laser diodes find application in optical amplification

4. Methodology and Apparatus

The experiment was conducted using a GaAs based laser of 670nm, a Peltier cooler, and a large area silicon photodiode as the photodetector, connected to a voltmeter. The Peltier cooler was used to transfer heat to the heat sink and change the temperature of the diode laser. Both the temperature and forward current through the diode laser were set and monitored using the control unit provided.

The laser and detector were both attached to a triangular rail and adjusted to be at the same height. The laser was adjusted so that the output beam fell on the detector. A voltmeter was attached to the photodetector to read the output in mV, which would later be converted to mW for analysis. The experiment was divided into three parts.

Experimental Measurements of the Laser Power Output at Constant Temperature

For the first part of the experiment, the temperature was set at approximately 20°C and the drive current was varied. The output voltage and corresponding drive current was recorded with the photodetector switched to the x1 sensitivity setting. The current was started at 0.0 mA and went to a maximum of no more than 43.0 mA. The data was plotted in Excel to create an L-I characteristic, as seen in Figure 3. The associated uncertainty was also plotted. From analysis of the data plot, the threshold current was determined and recorded. For data points above the threshold current, a line of best fit was plotted. The equation of this line was determined, and the slope of this line was recorded as the slope efficiency of the diode laser.

Experimental Measurements of Laser Power Output at Varying Temperature

For the second part of the experiment, the same process from the first part was followed at seven different temperatures between 5°C and 40°C. As with the first part of the experiment, the output voltage and corresponding drive current was recorded to a maximum current of no more than 43.0 mA. Seven L-I characteristics were produced and plotted on the same graph to show the influence of the temperature variation, as can be seen in Figure 4. For each plot, the associated uncertainty was also plotted. For each temperature, the plots were analyzed and threshold current and slope efficiencies were determined and recorded. From Eq. 1., Eq. 2 was derived and the characteristic temperature was empirically calculated.

$$T_0 = a \frac{T}{\ln(I/I_1)} \quad (2)$$

Experimental Measurements of Beam Spatial Cross-Sectional Power Distribution

For the third part of the experiment, the aperture was attached to the front of the photodetector. The diode laser was adjusted to be at the same height as the photodetector and moved to be 2.5 ± 0.2 cm from the photodetector. A white sheet of paper was used to view the laser beam and how it diverges. It was noted that the output beam was approximately 45° to the vertical. The sensitivity of the photodetector was switched to the x10 setting.

The temperature was set at approximately 20° and the current at 40.0 mA. The photodetector position was recorded and then displaced in the x-axis at a constant height. The detector output voltage was recorded at 0.5 ± 0.2 mm increments along the x-axis. Once the entire profile of the beam in the x-axis at that height was scanned, the detector was centered on the laser beam again at the original recorded position. The position of the photodetector along the y-axis was then displaced at a constant position on the x-axis. Once again, the detector output voltage was recorded at 0.5 ± 0.2 mm increments along the y-axis. After the entire beam had been scanned, the recorded data was plotted and beam profiles in the x-axis and y-axis were produced, as can be seen in Figure 5. For each plot, the associated uncertainty was also plotted. From the Full Width Half Maximum (FWHM), the beam divergence in the perpendicular and parallel to the junction, θ_1 and θ_2 respectively, were calculated.

5. Results

Laser Power Output as a Function of Forward Current at Constant Temperature

For the first part of the experiment the plot of the L-I characteristic is provided in Figure 3. The associated uncertainty from the detector at a sensitivity setting of $\times 1$ of $\pm 5\%$ is also provided for mW measurements. From the plot, the threshold current I_{th} was determined to be 24.50 mA by analyzing the point at which the diode laser reached lasing conditions. The slope efficiency was determined from the plotted line of best fit for data points above the threshold current as 0.2925 mW/mA. This means the laser is operating at approximately 29.25% efficiency at 20°C.

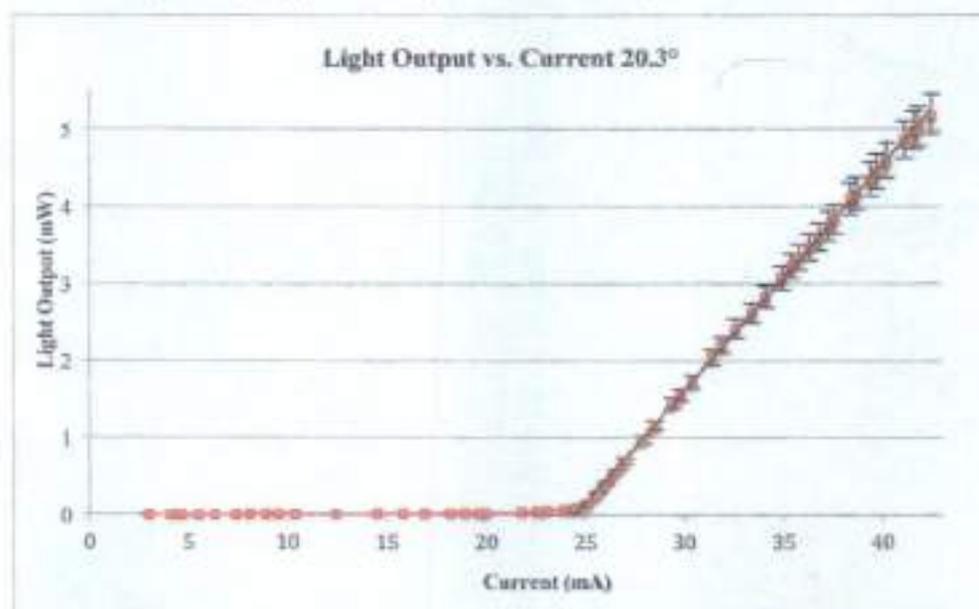


Fig. 3. L-I characteristic for diode laser at 20.3°C and varying drive current.

Temperature Dependence of the Threshold Current

For the second part of the experiment, the data collected was used to plot seven L-I characteristics at different temperatures, which is provided in the graph in Figure 4. The associated uncertainty from the detector at a sensitivity setting of $\times 1$ of $\pm 5\%$ is also provided for mW measurements. The threshold currents and slope efficiencies were determined from the plots as previously stated and are provided in Table 1. Furthermore, the characteristic temperature T_c was estimated, based on the experimental relation in Eq. 2, for each temperature. For further data analysis, the characteristic was calculated in K, rather than the temperature units used by the Peltier cooler, °C.

Table 1. Threshold Current, Characteristic Temperature, and Slope Efficiencies for various diode laser temperatures.

T (°C)	7.1	10.8	15.5	20.3	25.2	29.9	34.8	39.9
T (K)	280.25	283.95	288.65	293.45	298.35	303.05	307.95	313.05
I_{th} (mA)	22.705	23.216	23.721	24.50	24.814	25.533	26.126	27.087
T_c (K)	89.75	90.29	91.16	91.74	92.90	93.54	94.38	94.89
Slope Efficiency	31.21%	30.78%	29.89%	29.25%	27.82%	27.11%	25.96%	25.49%

6. Discussion

The experiment was completed and yielded good results. Over fifty measurements were recorded for the first part of experiment, with following parts having fewer measurements taken at low currents, which were deemed to not influence significant calculations (currents below approximately 20 mA). The results for the threshold current I_{th} , provided in Table 1, were consistent with the expected results [16]. It was observed that the threshold current varied with temperature, increasing as the temperature of the diode laser increased. Typical values for threshold currents of InGaAsP based diode lasers at room temperature range between 31-34 mA [17]. The diode laser used for this experiment is GaAs based with a GaInP active layer and AlGaInP p-type and n-type doped cladding layers, thus the resulting threshold currents can be said to be comparable with known results.

The empirically calculated values for the characteristic temperature T_c , were within the expected range of values. However, the values varied slightly with temperature, which was not expected. This variation was only by 5% between the measurements taken at 7.1°C and 39.9°C. Typical values for T_c , for GaAs/AlGaAs based diode lasers are between 60K to 150K, and consistent with the calculated results [17, 18]. The value of T_c , is highly dependent on the active layer used for the diode laser [17]. Specifically, larger values of the threshold current can be expected for lasers that use semiconductors with wider band gaps, and higher energy gaps, such as GaN as previously mentioned [8, 11, 19].

It should be noted that the calculated T_c , was only a proportional empirical relation with a final value needing multiplication by a constant based on the dimensions of the diode material. Actual values for the characteristic temperature use the current density through the device. However, additional research has shown that the relation used for calculating the characteristic temperature only holds for a small range of temperatures and current densities, with other equations used when determining the characteristics of diode lasers at very low temperatures [20]. Higher characteristic temperature values correspond to lower threshold current values. This provides a laser that is more thermally stable. Characteristic temperature is a measurement of thermal sensitivity, with good lasers having high values of T_c . Such diode lasers with large characteristic temperatures would be useful in fibre optics and other telecommunication systems [21, 22].

For the final part of the experiment, it was observed that the laser beam was diverging and formed an ellipse that was not directly aligned with the x-y axis. The angle of the laser beam was approximately 45° to the vertical, with respect to the elliptical beam shape being vertical. The diffraction of laser light through a small aperture is expected to form diffuse circular discs, Airy's disc, followed by faint concentric circles [23, 24]. The calculated values for the divergence of $\theta_1 = 21.8^\circ \pm 1.6^\circ$ and $\theta_2 = 9.1^\circ \pm 0.7^\circ$ were within the expected limitation. Typical angle values for the perpendicular axis is 30°, up to 40°, and parallel axis of 10° up to 12° [17-19]. The calculated values are lower than those of the expected values. This is due to the alignment of the beam and the diode laser. The method used for data collection did not scan the entire width of the beam profile. To properly determine the angular divergence, the full length and width of the beam must be measured by either changing the angle of the beam or simultaneously changing the x and y displacement of the sensor rather than keeping one constant. However, considering the limitation, the calculated divergence angles are acceptable.

The plots of the beam profile use the detector output readings in mV rather than light power in mW. This is because the x10 sensitivity setting of the photodetector was required for readings and the lab manual did not include information on the uncertainty of the detector sensitivity at the x10 setting. As the resulting values for the divergence angles are agreeable with known values, the uncertainty of the sensitivity of the detector at the x10 setting may be considered insignificant enough to have not caused any discrepancies with the final results.

To further expand this experiment, taking a full scan of the beam profile would have shown more accurate results to compare with the known divergence angles. From a full beam scan, an accurate full 2D cross-sectional map of the power distribution of the beam could have been plotted.

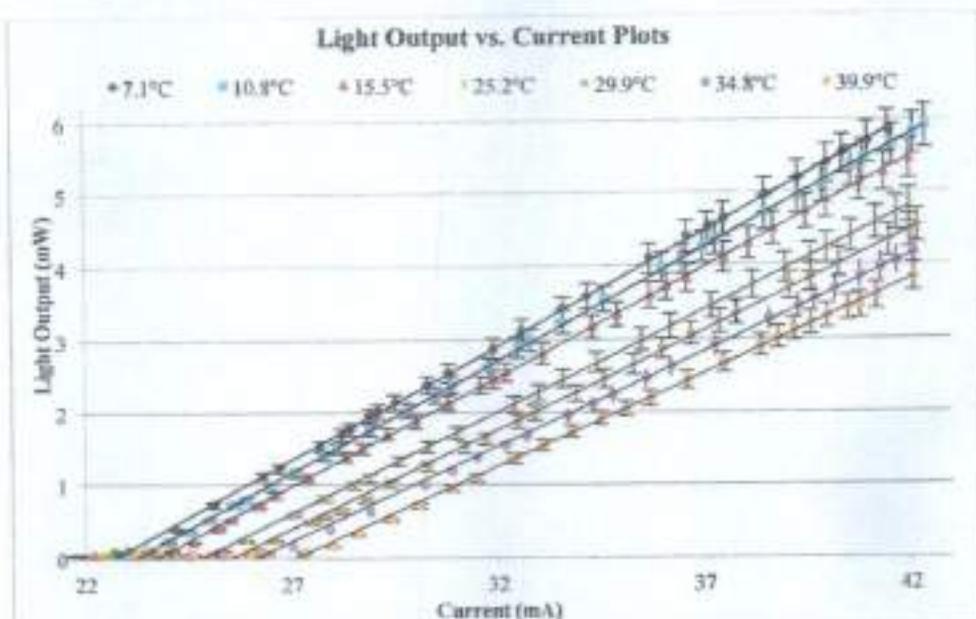


Fig. 4. L-I characteristics for diode laser at varying temperatures between 5°C and 40°C and varying drive current below 43.0 mA.

Analysis of Beam Profile and Beam Divergence Angle

For the third part of the experiment, Figure 5 shows the beam profile in the x-axis and y-axis. The associated uncertainty in the displacement of the photodetector of ± 0.2 mm is also provided. No associated uncertainty is provided for the detector output as the laboratory manual did not provide the uncertainty at a sensitivity setting of $\times 10$. The beam divergence in the perpendicular and parallel was calculated from the Full Width Half Maximum (FWHM), as $\theta_1 = 21.8^\circ \pm 1.6^\circ$ and $\theta_2 = 9.1^\circ \pm 0.7^\circ$ at a distance of 2.5 ± 0.2 cm.

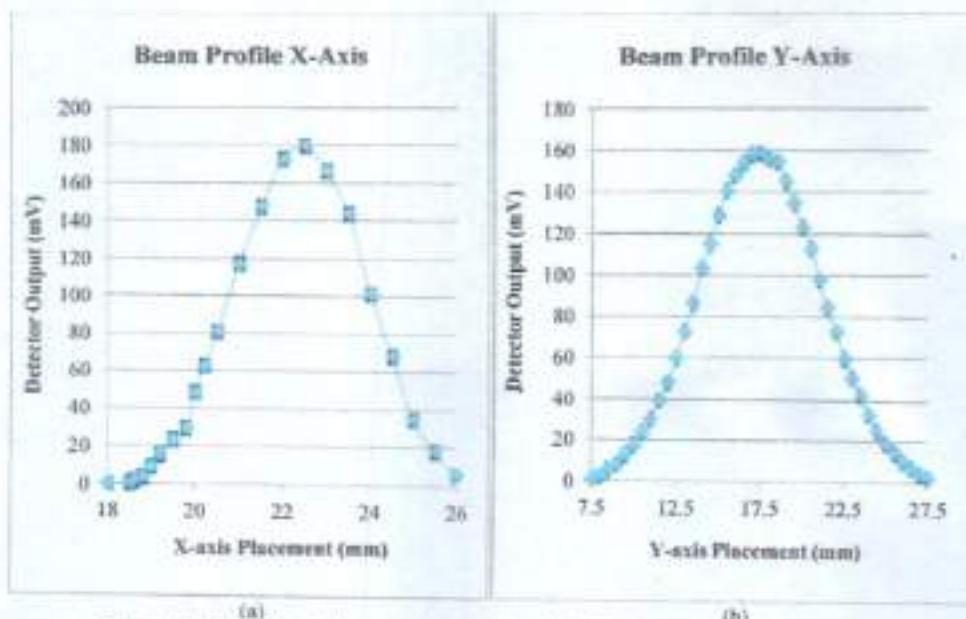


Fig. 5. Beam profile: (a) along x-axis at constant y-height; (b) along y-axis at constant x-axis displacement.

7. Conclusion

The experiment was conducted to explore the characteristics of a diode laser. The temperature dependence of the threshold current I_{th} was investigated and L-I characteristic plots for various temperatures were produced and analyzed. The characteristic temperature T_0 was estimated using the empirical relation given. The optical properties of the output beam profile were investigated and the divergence angles of the laser beam are calculated. All results were within the experimental uncertainty of expected values and consistent with other research literature.

PATTAMUNDAI COLLEGE
PATTAMUNDAI

DEPARTMENT OF PHYSICS



PROJECT
ON

“VLSI FABRICATION TECHNOLOGY”

PREPARED BY 3RD YEAR STUDENTS

AND

SUPERVISED BY -: Dr. Ramesh Kumar Sahoo

March-2022

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Signature of the
Supervisor

R. Sahoo
signature of
H.O.D. Physics

REPORT

A project on "VLSI FABRICATION TECHNOLOGY" was prepared by students of Department of Physics during the month of March 2022. Two members of student participated in the project work. They collected several materials on the concerned topic from different Libraries and other studious Places. The department faculties co-operated them in all these works and this project is original.

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Principal
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DEPARTMENT OF PHYSICS,

PATTAMUNDAI COLLEGE, PATTAMUNDAI.

SESSION 2021-2022

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CONTENTS

- Introduction
- IC Fabrication Steps
- VLSI Processes
- VLSI Layout
- Beyond 20nm Technology
- Conclusion
- Reference

Introduction

Since the first edition of this text, we have witnessed a fantastic evolution in **VLSI** (very-large-scale integrated circuits) technology. In the late 1970s, non-self-aligned metal gate MOSFETs with gate lengths in the order of 10 μm were the norm. Current VLSI fabrication technology is already at the physical scaling limit with gate lengths in the 20-nm regime. This represents a reduction in device size of almost 1000x, along with an even more impressive

increase in the number of devices per VLSI chip. Future development in VLSI technology must rely on new device concepts and new materials, taking quantum effects into account. While this is a very exciting time for researchers to explore new technology, we can also be assured that the "traditional" **CMOS** and **BiCMOS** (bipolar CMOS) fabrication technology will continue to be the workhorse of the microelectronic industry for many more years to come.

The purpose of this appendix is to familiarize the reader with VLSI fabrication technology. Brief explanations of standard VLSI processing steps are given. The variety of devices available in CMOS and BiCMOS fabrication technologies are also presented. In particular, the availability of components in the **IC** (integrated circuit) environment that are distinct from discrete circuit design will be discussed. In order to enjoy the economics of integrated circuits, designers have to overcome some serious device limitations (such as poor device tolerances) while exploiting device advantages (such as good component matching). An understanding of device characteristics is therefore essential in designing high-performance custom VLSIs.

This appendix will consider only silicon-based (Si) technologies. Although other compound materials in groups III through V, such as gallium arsenide (GaAs) and aluminum gallium nitride (AlGaN), are also used to implement VLSI chips, silicon is still the most popular material, with excellent cost-performance trade-off. Recent development in SiGe and strained-silicon technologies will further strengthen the position of Si-based fabrication processes in the microelectronic industry for many more years to come.

Silicon is an abundant element and occurs naturally in the form of sand. It can be refined using well-established purification and crystal growth techniques. It also exhibits suitable physical properties for fabricating active devices with good electrical characteristics. In addition, silicon can be easily oxidized to form an excellent insulator, SiO_2 (glass). This native oxide is useful for constructing capacitors and MOSFETs. It also serves as a diffusion barrier that can mask against unwanted impurities from diffusing into the high-purity silicon material. This masking property allows the electrical properties of the silicon to be altered in predefined areas. Therefore, active and passive elements can be built on the same piece of material (substrate). The components can then be interconnected using metal layers (similar to those used in printed-circuit boards) to form a monolithic IC.

IC Fabrication Steps

The basic IC fabrication steps will be described in the following sections. Some of these steps may be carried out many times, in different combinations and/or processing conditions during a complete fabrication run.

Silicon Wafers

The starting material for modern integrated circuits is very-high-purity, single-crystal silicon. The material is initially grown as a single crystal ingot. It takes the shape of a steel-gray solid cylinder 10 cm to 30 cm in diameter and can be one to two meters in length. This crystal is then sawed (like a loaf of bread) to produce circular **wafers** that are 400 μm to 600 μm thick (a micrometer, or micron, μm , is a millionth of a meter). The surface of the wafer is then polished to a mirror finish using chemical and mechanical polishing (CMP) techniques. Semiconductor manufacturers usually purchase ready-made silicon wafers from a supplier and rarely start their fabrication process in ingot form.

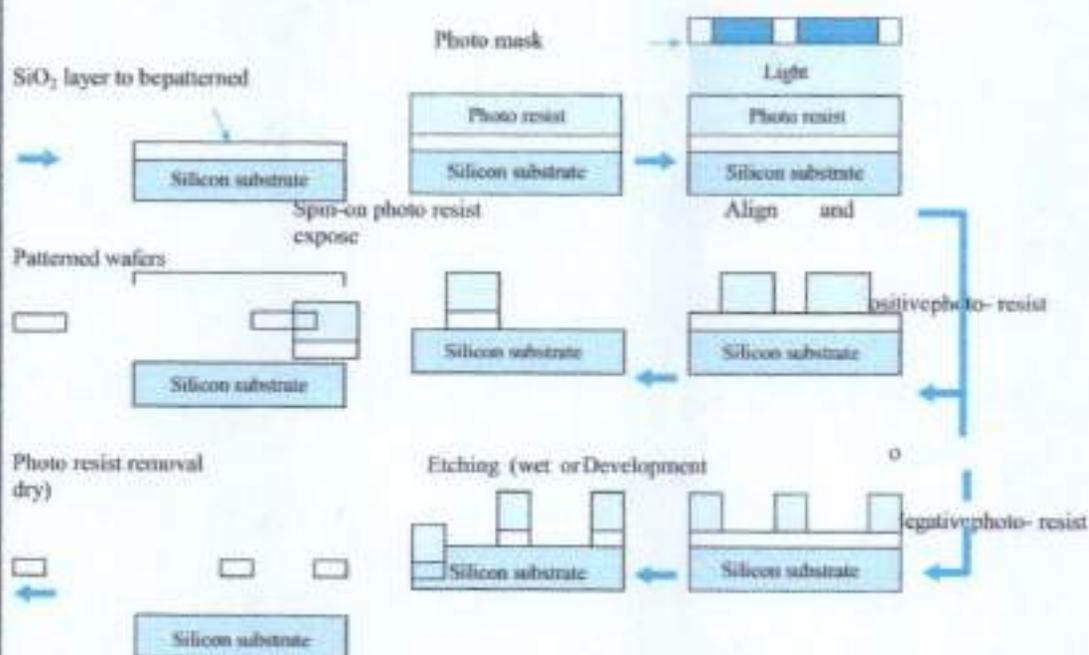
Oxidation

In **oxidation**, silicon reacts with oxygen to form silicon dioxide (SiO_2). To speed up this chemical reaction, it is necessary to carry out the oxidation at high temperatures (e.g., 1000–1200°C) and inside ultraclean furnaces. To avoid the introduction of even small quantities of contaminants (which could significantly alter the electrical properties of the silicon), it is necessary to operate in a **clean room**. Particle filters are used to ensure that the airflow in the processing area is free from dust. All personnel must protect the clean-room environment by wearing special lint-free clothing that covers a person from head to toe.

Photolithography

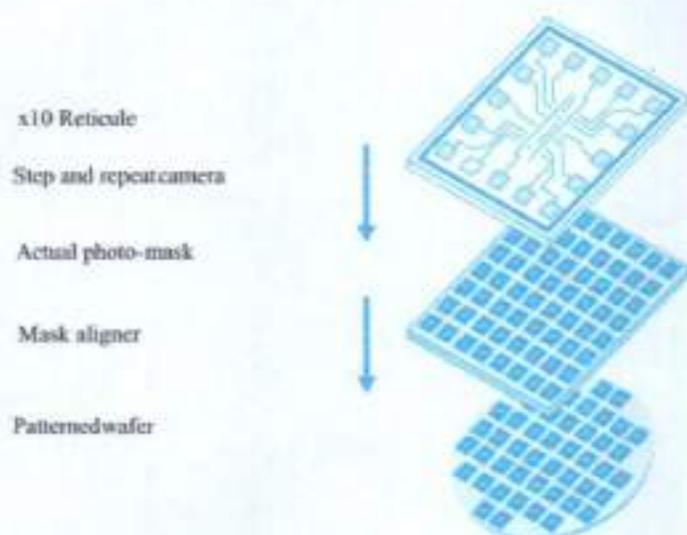
Mass production with economy of scale is the primary reason for the tremendous impact VLSI has had on our society. The surface patterns of the various integrated-circuit components can be defined repeatedly using photolithography. The sequence of photolithographic steps is as illustrated in Fig.

The wafer surface is coated with a photosensitive layer called photo resist, using a spin-on technique. After this, a photographic plate with drawn patterns (e.g., a quartz plate with chromium layer for patterning) will be used to selectively expose the photo resist under a deep ultraviolet illumination (UV). The exposed areas will become softened (for positive photo resist). The exposed layer can then be removed using a chemical developer, causing the mask pattern to be duplicated on the wafer. Very fine surface geometries can be reproduced accurately by this technique. Furthermore, the patterns can be projected directly onto the wafer, or by using a separate photo mask produced by a 10X "step and repeat" reduction technique as shown in Fig.



Photolithography using positive or negative photo resist.

VLSI Fabrication Technology



Conceptual illustration of a step-and-repeat reduction technique to facilitate the mass production of integrated circuits.

Etching

To permanently imprint the photographic patterns onto the wafer, chemical (**wet**) etching or RIE **dry etching** procedures can be used. Chemical etching is usually referred to as **wet etching**. Different chemical solutions can be used to remove different layers. For example, hydrofluoric (HF) acid can be used to etch SiO_2 , potassium hydroxide (KOH) for silicon, phosphoric acid for aluminum, and so on. In wet etching, the chemical usually attacks the exposed regions that are not protected by the photo resist layer in all directions (**isotropic etching**).

Diffusion

Diffusion is a process by which atoms move from a high-concentration region to a low-concentration region. This is very much like a drop of ink dispersing through a glass of water except that it occurs much more slowly in solids. In VLSI fabrication, this is a method to introduce impurity atoms (dopants) into silicon to change its resistivity. The rate at which dopants diffuse in silicon is a strong function of temperature. Diffusion of impurities is usually carried out at high temperatures (1000–1200°C) to obtain the desired doping profile. When the wafer is cooled to room temperature, the impurities are essentially “frozen” in position.

Ion Implantation

Ion implantation is another method used to introduce impurities into the semiconductor crystal. An ion implanter produces ions of the desired dopant, accelerates them by an electric field, and allows them to strike the semiconductor surface. The ions become embedded in the crystal lattice. The depth of penetration is related to the energy of the ion beam, which can be controlled by the accelerating-field voltage. The quantity of ions implanted can be controlled by varying the beam current (flow of ions). Since both voltage and current can be accurately measured and controlled, ion implantation results in impurity profiles that are much more accurate and reproducible than can be obtained by diffusion. In addition, ion implantation can be performed at room temperature. Ion implantation normally is used when accurate control of the doping profile is essential for device operation.

Chemical Vapor Deposition

Chemical vapor deposition (CVD) is a process by which gases or vapors are chemically reacted, leading to the formation of solids on a substrate. CVD can be used to deposit various materials on a silicon substrate including SiO_2 , Si_3N_4 , poly silicon, and so on. For instance, if silane gas and oxygen are allowed to react above a silicon substrate, the end product, silicon dioxide, will be deposited as a solid film on the silicon wafer surface. The properties of the CVD oxide layer are not as good as those of a thermally grown oxide, but they are sufficient to allow the layer to act as an electrical insulator. The advantage of a CVD layer is that the oxide deposits at a faster rate and a lower temperature (below 500°C).

Metallization

The purpose of metallization is to interconnect the various components (transistors, capacitors, etc.) to form the desired integrated circuit. Metallization involves the deposition of a metal over the entire surface of the silicon. The required interconnection pattern is then selectively etched. The metal layer is normally deposited via a sputtering process. A pure metal disk (e.g., 99.99% aluminum target) is placed under an Ar (argon) ion gun inside a vacuum chamber. The wafers are also mounted inside the chamber above the target. The Ar ions will not react with the metal, since argon is a noble gas. However, the ions are made to physically bombard the target and literally knock metal atoms out of the target. These metal atoms will then coat all the surface inside the chamber, including the wafers. The thickness of the metal film can be controlled by the length of the sputtering time, which is normally in the range of 1 to 2 minutes. The metal interconnects can then be defined using photolithography and etching steps.

Packaging

A finished silicon wafer may contain several hundreds of finished circuits or chips. A chip may contain from 10 to more than 10^8 transistors; each chip is rectangular and can be up to tens of millimeters on a side. The circuits are first tested electrically (while still in wafer form) using an automatic probing station. Bad circuits are marked for later identification. The circuits are then separated from each other (by dicing), and the good circuits (dies) are mounted in packages (headers). Examples of such IC packages are given in Fig. A.4. Fine gold wires are normally used to interconnect the pins of the package to the metallization pattern on the die. Finally, the package is sealed using plastic or epoxy under vacuum or in an inert atmosphere.

VLSI Processes

Integrated-circuit fabrication technology was originally dominated by bipolar technology. By the late 1970s, metal oxide semiconductor (MOS) technology became more promising for VLSI implementation with higher packing density and lower power consumption. Since the early 1980s,

complementary MOS (CMOS) technology has almost completely dominated the VLSI scene, leaving bipolar technology to fill specialized functions such as high-speed analog and RF circuits. CMOS technologies continue to evolve, and in the late 1980s, the incorporation of bipolar devices led to the emergence of high-performance bipolar-CMOS

(BiCMOS) fabrication processes that provided the best of both technologies. However, BiCMOS processes are often very complicated and costly, since they require upward of 15 to 20 masking levels per implementation—standard CMOS processes by comparison require only 10 to 12 masking levels.

The performance of CMOS and BiCMOS processes continues to improve with finer lithography resolution. However, fundamental limitations on processing techniques and semiconductor properties have

prompted the need to explore alternate materials. Newly emerged SiGe and strained-Si technologies are good compromises to improve performance while maintaining manufacturing compatibility (hence low cost) with existing silicon-based CMOS fabrication equipment.

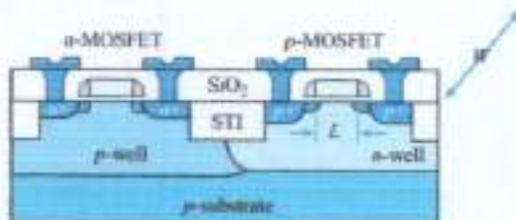
In the subsection that follows, we will examine a typical CMOS process flow, the performance of the available components, and the inclusion of bipolar devices to form a BiCMOS process.

Integrated Devices

Besides the obvious n - and p -channel MOSFETs, other devices can be obtained by appropriate masking patterns. These include pn junction diodes, MOS capacitors, and resistors.

MOSFETs

The n -channel MOSFET is the preferred device in comparison to the p -MOSFET. The electron surface mobility is two to three times higher than that for holes. Therefore, with the same device size (W and L), the n -MOSFET offers higher current drive (or lower on-resistance) and higher Trans conductance.



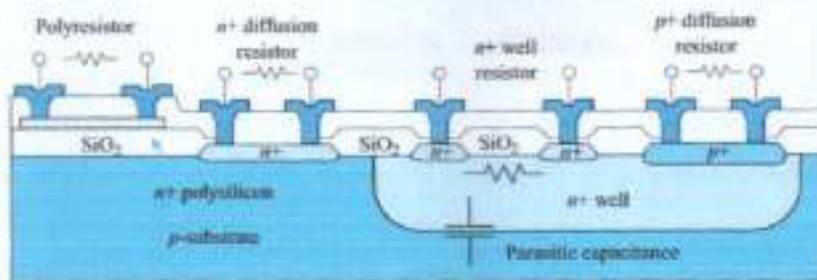
Resistors

Resistors in integrated form are not very precise. They can be made from various diffusion regions as shown in Fig. Different diffusion regions have different resistivity. The n well is usually used for medium-value resistors, while the n and p diffusions are useful for low-value resistors. The actual resistance value can be defined by changing the length and width of diffused regions. The tolerance of the resistor value is very poor (20–50%), but the matching of two similar resistor values is quite good

(5%). Thus circuit designers should design circuits that exploit resistor matching and should avoid designs that require a specific resistor value.

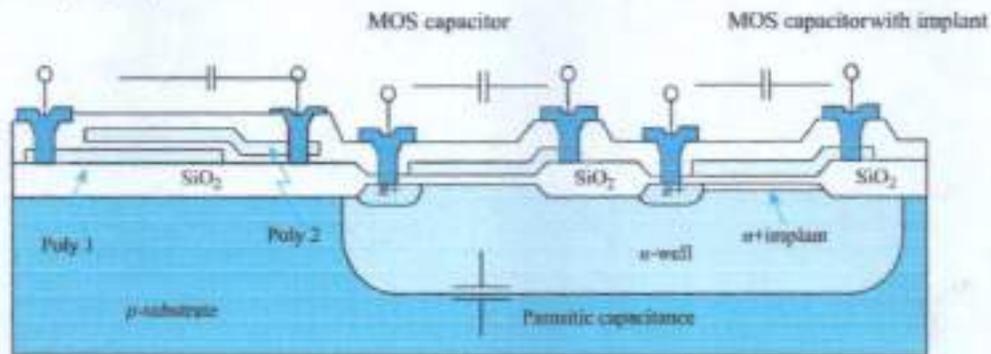
Capacitors

Two types of capacitor structure are available in CMOS processes: MOS and inter poly capacitors. The latter are also similar to metal–insulator–metal (MIM) capacitors. The cross sections of these structures are as shown in Fig. The MOS gate capacitance, depicted by the center structure, is basically the gate-to-source capacitance of a MOSFET. The capacitance value is dependent on the gate area. The oxide thickness is the same as the gate oxide



Cross sections of various resistor types available from a typical n -well CMOS process.

Inter poly Capacitor



Inter poly and MOS capacitors in an n -well CMOS process.

Thickness in the MOSFETs. This capacitor exhibits a large voltage dependence. To eliminate this problem, an additional n^+ implant is required to form the bottom plate of the capacitors, as shown in the structure on the right. Both these MOS capacitors are physically in contact with the substrate, resulting in a large parasitic pn junction capacitance at the bottom plate.

Pn Junction Diodes

Whenever n -type and p -type diffusion regions are placed next to each other, a pn junction diode results. A useful structure is the n -well diode. The diode fabricated in an n well can provide a high breakdown voltage. This diode is essential for the input clamping circuits for protection against electrostatic discharge. The diode is also very useful as an on-chip temperature sensor by monitoring the variation of its forward voltage drop.

VLSI Layout

The designed circuit schematic must be transformed into a layout that consists of the geometric representation of the circuit components and interconnections. Today, computer-aided design tools allow many of the conversion steps, from schematic to layout, to be carried out semi- or fully automatically. However, any good mixed-signal IC designer must have practiced full custom layout at one point or another. An example of a CMOS inverter can be used to illustrate this procedure.

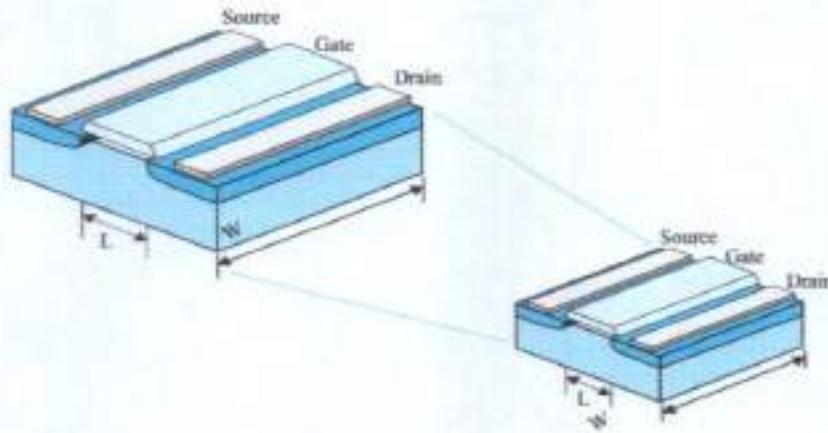
The circuit must first be "flattened" and redrawn to eliminate any interconnection crossovers, similar to the requirement of a printed-circuit-board layout. Each process is made up of a specific set of masking layers. In this case, seven layers are used. Each layer is usually assigned a unique color and fill pattern for ease of identification on a computer screen or on a printed color plot. The layout begins with the placement of the transistors. For illustration purposes, the p and n MOSFETs are placed in an arrangement similar to that shown in the schematic. In practice, the designer is free to choose the most area-efficient layout. The MOSFETs are defined by the active areas overlapped by the "poly 1" layer. The MOS channel length and width are defined by the width of the "poly 1" strip and that of the active region, respectively. The p -MOSFET is enclosed in an n well. For more complex circuits, multiple n wells can be used for different groups of p -MOSFETs. The n -MOSFET is enclosed by the n diffusion mask to form the source and drain, while the p -MOSFET is enclosed by the p diffusion mask. Contact holes are placed in regions where connection to the metal layer is required. Finally, the "metal 1" layer completes the interconnections.

The corresponding cross-sectional diagram of the CMOS inverter along the AA' plane is as shown in Fig. A.15. The poly-Si gates for both transistors are connected to form the input terminal, X . The drains of both transistors are tied together via "metal 1" to form the output terminal, Y . The sources of the n - and p -MOSFETs are connected to GND and V_{DD} , respectively. Note that butting contacts consist of side-by-side n/p diffusions that are used to tie the body potential of the n - and p -MOSFETs to the appropriate voltage levels.

When the layout is completed, the circuit must be verified using CAD tools such as the circuit extractor, the design rule checker (DRC), and the circuit simulator. Once these verifications have been satisfied, the design can be "taped out" to a mask-making facility.

Beyond 20 nm Technology

The rapid advancement of VLSI fabrication technology has followed a prediction called Moore's Law for more than four decades. In 1965, Gordon Moore, one of the cofounders



MOSFET scaling consists of the reduction of both the surface and vertical dimensions. In addition, modification of the doping profiles and choice of materials are also necessary.

of Intel, foresaw that the number of transistors that can be integrated onto a VLSI chip would roughly double every two years. In order to achieve this, the size of the transistor has to be reduced accordingly. Otherwise, the size of the VLSI chip would have grown to an unacceptable size, leading to low yield and high cost. Instead of redesigning a fabrication technology from scratch every time, a scaling procedure is normally carried out. The scaling process is not only an optical shrink of the device surface layout, it also requires the reduction in vertical dimensions such as gate oxide thickness, source and drain junction depths, etc. The effect of MOSFET scaling is illustrated. VLSI fabrication technology is categorized by the minimum dimension that it can define. This is usually referred to as the channel length of the MOS gate. The reduction in device dimensions not only allows higher integration density, the shorter channel length and closer proximity of the devices also allow higher switch speed, hence better performance. As a rule of thumb, scaling cannot be carried out with an aggressive factor. Normally, 50% reducing in dimensions is achieved every two generations. Therefore, a scaling factor of approximately 0.7 is normally used. This is why we have technology nodes such as 1 μm in 1990, to 0.7 μm , 0.5 μm , 0.35 μm , 0.25 μm , 0.18 μm , 0.13 μm , 90 nm and so on.

Conclusion

This appendix presents an overview of the various aspects of VLSI fabrication procedures. This includes component characteristics, process flows, and layouts. This is by no means a complete account of state-of-the-art VLSI technologies. Interested readers should consult other references on this subject for more detailed descriptions.

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A PROJECT REPORT
ON
“POULTRY FARMING IN
PATTAMUNDAI LOCALITY”

Department of Zoology
Pattamundai College
Pattamundai

PROJECT REPORT ON

**“POULTRY FARMING IN
PATTAMUNDAI LOCALITY”**

SESSION - 2021-22

PREPARED BY

DEPARTMENT OF ZOOLOGY



**PATTAAMUNDAI COLLEGE
PATTAMUNDAI, KENDRAPARA
ODISHA- 754215**

REPORT

A Project titled "Poultry Farming In Pattamundai Locality" was undertaken by 15 students of Zoology department guided by Prof D.K. Bhuyan , Reader in Zoology in this session. Samples were collected by students from different Poultry Farms of Pattamundai Locality. All the teachers of the department help them during the project work. The Demonstrators in the department also helped the students during their experimental work . The performances of students were found to be satisfactory.

S. M. Mishra
12.04.2023

Signature of Supervisor

AC
12-4-22

Signature of HOD

[Signature]
12-4-22

Principal
Pattamundai college

Head of The Department
Zoology
Pattamundai College.

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Dilip Kumar Dey,
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Pattamundai College.

ABSTRACT

Rural Environment has been transformed by the adapting model breads of livestock together with the associated packages of external inputs such as fertilizers, pesticides, antibiotics, machinery etc. necessary to make these productive.

As agriculture has developed, there has also been an increasing in population of poultries. The poultry waste and the biochemicals deposited on land and sometimes mixed with water to cause land, water and air pollution, so that the overall environment of the area under study has gone into critical stage due to these conditions.

OBJECTIVE

Study of impacts of changes in animal husbandry practice like poultry room over a period of time in a given locality of village on a local environment.

Village :-Kasananta

P.O. :-Kasananta

District :-Kendrapara

State :- Odisha

Country :- India

INTRODUCTION

Odisha continues to be one of the poorest and backward state of India. Though it is endowed with the natural resources, its 87% population is rural based in which 22% and 16% belong to ST and SC communities respectively. Economy of Odisha is mainly based on agriculture. Odisha agriculture is mainly crop based. But other components like diary, fishery and poultry production etc. are very much important for economic development of people.

MATERIALS AND METHODS

An extensive survey has been done along different parameters, such as locality and area of poultry farms, types of birds, types of shelter, types of animals, feed methods of preservation and processing of products, medicare to the birds, disposal of wastes.

OBSERVATION

There are two poultry farms in this village.

1. Locality in which Poultry Farm is Established:

The locality of poultry farm in rural based with a lot of open space nearby. This residential units are 60 ft. away to the west side of the poultry units. There is no hinderance for people nearby residential home.

2. Area of Poultry Farms:

200 – 300 sq. ft. areas of one or two poultry farms are established by one or two educated persons of this village.

There are open space to the front east – 8 ft. and back west – 3 ft. and other two sides 3 ft. each of the poultry farms.

3. Types of Birds:

The birds like Black Rock Broiler, Kalinga Brown (Hybrid hen), Giriraj Broiler, China Fowl/Hen etc. are kept within farms.

i. *Black Rock Broiler:*

The colour of wings of those birds are black. The weight of one day chick is 3.8 grams. Usually the weight of fowl/hen is 2.5 to 3.5 kg within 40 weeks.

ii. *Kalinga Brown Fowl/Hen:*

There birds are hybrids of R.R.I. hen and W.L.H. fowl. The weight of one day chick is 3.5 gm. Each hen produces 270 to 272 eggs per year. They need either 2.240 kg or

3.760 kg feed to produce 12 dozen or 1kg eggs respectively. The weight of each egg is 50 gm and the colour of egg is brown.

iii. Giriraj Broiler:

These birds grow very fast and the weight of the chick is 1.25 kg and 1.5 kg for 7 and 8 weeks respectively. They produce 120 to 150 eggs per year. The weight of adult fowls/hens is 3 to 4 kg.

iv. China Fowl/Hen

The weight of chicks within 12 to 16 weeks is 1kg. Usually they produce eggs from March to September. Each hen produces 120 eggs per year. The meat of china fowl/hen is 80% more than that of other fowls/hens.

4. Shelter for Poultry:

One is 200 sq. ft. for 200 birds and another is 400 sq. ft. for 400 birds. Mostly these are pucca buildings.

Table – 1 (shelter needed for each fowl/hen):

Types of House	Deep Litter House	Net House
Breeding House	0.4 sqft/chick	0.5 sqft/chick
Grower House	1 sqft/Grower (adult)	0.6 sqft/grower
Breeding with Rearing House	1 sqft/bird (fowl/hen)	0.6 sqft/bird (fowl/hen)
Layer House	1 sqft/layer	0.7 -0.9 sqft/layer

For every stage of fowl/hen different type of shelter or house are needed.

5. Feed for Fowls/Hens:

Table – 2 (Types of feed for fowl/hen):

Name of Food or Grain	Chick 0-8 Weeks (kg.)	Grower 9-16 Weeks (kg.)	Layer Breeder 17 Weeks or More (kg.)	Broiler Starter 0-6 Weeks (kg.)	Broiler Finisher 6 Weeks or More (kg.)
Maize Powder	45	45	45	49	60
Rice Polish	22	25	15	10	07
Soybean Mill	30	19	27	38	30
Boiled Rice Brun	-	08	06	-	-
Mineral Mixture	03	03	03	03	03
Mineral and Powder	-	-	04	-	-
Total	100	100	100	100	100

Table -3 (Feeds with vitamins with other medicines per quintal)

Name of vitamins / medicines	Chick 0-8 Weeks (kg.)	Grower 9-16 Weeks (kg.)	Layer Breeder 17 Weeks or More (kg.)	Broiler Starter 0-6 weeks (kg.)	Broiler Finisher 6 Weeks or More (kg.)
Vitamin A+B2+D3+K2+D5 (g)	10	10	10	10	10
B Complex with E (g)	25	25	25	25	-
Net Fin - 200 g	50	50	50	50	50
Merivoit - 100 g	22	22	10	22	22
Kodan - 100 g	100	100	-	100	100
Calcivimin Fort (g)	250	250	250	500	500
Lysesene (g)	100	100	50	100	100
DAL - Methionine (g)	100	75	50	100	50
Salt (g)	500	50	500	500	500

Crude Proteins (Minimum %)	20	16	13	23	20
Crude Fiber (Maximum %)	07	08	08	06	06
Salt (Maximum %)	0.6	0.6	0.6	0.6	0.6
Calcium (Minimum %)	1.0	1.0	3.0	1.2	1.2
A Level Phosphorus (Minimum %)	0.5	0.5	0.5	0.5	0.5
Metabolizable Energy (kcal/kg.)	2600	2500	2600	2800	29000

6. Provision for Waste Disposal:

The sheds of the birds of these one or two poultry farms are cleaned and there is provision for disposal of the waste materials mainly litter.

DISCUSSION

As agriculture has developed, there has been an increase in population of cattle. Due to increase in population and decrease in agriculture land, people also want to do Poultry Farming for increase their financial condition. Now-a-days more people are interested to established the Poultry Farm.

Effect of Poultry Wastes:

The poultry waste which is composed of rice spun, wooden powder and litter, is washed out with water and deposited on wet slurry on the land. The slurry deposited on soil, may be washed or may run into drains, canals and ponds causing water pollution.

The poultry wastes are regarded as an important source of soil fertility, but they also give rise to serious problems of odors and causes air pollution. The water enters into water sources and cause water pollution when run off carries the wastes into water bodies. Such wastes containing pathogenic organisms are ultimately transmitted to human and cause air and water borne diseases.

Effect of Medicine:

The medicines used for curing diseased fowls/hens are mixed with water to cause water pollution. These chemicals have been found to be the cause for arthritis, skin diseases, serious eye, kidney and liver disorder to local people.

If the fowls/hens are attacked by severe diseases they would die. The dead bodies give bad odor and create air pollution. So dead bodies should be dug inside the hole which would be decomposed by micro-organisms. So that the farms are well maintained.

There is no waste deposited inside the farm. If their waste material deposited, the bird will fall on poultry diseases. The farms are sprayed with sanital / pine oil / phenyl after cleaning. The poultry waste, extra feed and manure i.e., phosphate etc. are put in a big hole for preparing compost, which are being used for agriculture. The birds are treated with approved medicare.

IMPLEMENTATION

Looking to adverse effect of deposited poultry wastes, medicines, dead bodies of fowls/hens etc. current emphasis is being stressed on the properly use of litter of fowl/hens, sanitation of poultry farms.

1. Provision for Waste Disposal:

The shed of the birds of poultry farms are cleaned and there is provision for disposal of waste material (mainly litter of fowls/hens).

Litters are used as manure in the field for healthy growth of crops and vegetables. It is also used as fish food. The normal rate of litters for 1 kg. is Rs. 5/- which is being sold to local farmers.

2. Litter Used for Farm Yard Manures:

Farm Yard manures are bulk organized manure resulting from decomposed mixture of dung and urine of farm animals (Cow etc.) with the litter of fowls/hens from poultry farms on average, well-rotted FYM contains 0.5-1.0% N, 0.15-0.20% P_2O_5 and 0.5-0.6% K_2O , desired C:N ratio in FYM should not exceed 15-20.

3. Sanitation for Poultry Farms:

i. Preparation of Brood House Before Birth of Chicks:

The house should be vacant and cleaned the wall and floor with Costic Soda. All the materials of poultry farm should be cleaned with phenyl and then with potassium permanganate water. After the cleaning these materials should be dried and kept before 8 days. Water line or channel should be cleaned by phenyl. The floor and the rooms etc. should be sprayed with 10% formalin solution (i.e., 450ml – 10 lt. water) and kept close the room for 24 hours. The wall of the house should be painted with mixture of lime and malathion powder. The rice bran or saw dust should be spread on the floor and then old news paper should be covered over them. Maize floor or suji powder should be maintained at 95° F before coming of the chicks. Then the feeds and water should be supplied slowly to the chicks.

ii. Maintenance of Grower (For 9 to 16 weeks):

Grower should be kept inside grower or rearing room. These rooms should be well ventilated and also kept open space for their walking and running. They should be eating their appropriate feed and water. After 8-10 weeks the hair of grower fowl should be cut.

iii. Maintenance of Layers:

The feed should be supplied to layers according to the proportion of feed, seasons and weather. The house of

layers also kept some open space for their walking and running. They should be taken care during summer, rainy and winter. The box for production of eggs for 5 layers should be kept in each room and good rice bran/saw dust should be spread on the floor. The egg box should be cleaned in every week and poured good rice bran. The egg should be collected 4 to 6 times from deep litter house. The birds should be saved from mice and other animals, insects etc. the dead birds should be burned or dug into the soil.

iv. Medicare to the Birds (Chart for Injection):

The house should be vacant and cleaned the wall and floor with Costic Soda. All the materials of poultry farm should be cleaned with phenyl and then with potassium permanganate water. After the cleaning these materials should be dried and dept before 8 days. Water line or channel should be cleaned by phenyl.

Sl. No.	Age	Name of Vaccines	Place for Giving Vaccines	Disc
1	1 day	Morax Disease	Below the skin of Neck	0.2 ml
2	5-7 days	F-1 or Lasota (For Ranikhata Disease)	On Nostril of Nose or on eye	1 drop
3	21 days	F-1 or Lasota (For Ranikhata Disease)	Eye	1 drop
4	6 weeks	Chicken Pox	Injection syringe on Wings Below wings in the skin	2 times

5	8 weeks	Ranikhata Disease (R ₂ B)	Below wings in the skin	0.5 ml
6	12 weeks	Chicken Pox	Through injection syringe	2 times
7	16 weeks	Ranikhata Disease (R ₂ B)	Below the skin of the wings	0.5 ml

CONCLUSION

If the poultry farmer will take proper sanitation care, of their poultry farms, then the fowls/hens would live healthily. So that the economic condition of these farmers will be improved. There may be less environmental pollution of the management practices and monitoring of the poultry produce will be well maintained by the consolation of experienced concerned doctors and scientists and proper feedback to them.

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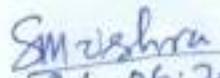
PROJECT ON "POULTRY FARMING IN PATTAMUNDAI LOCALITY"

DEPARTMENT OF ZOOLOGY

SESSION- 2021-22

PATTAMUNDAI COLLEGE, PATTAMUNDAI, KENDRAPARA, ODISHA

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-041	Laxmipriya Mallik	-041	Laxmipriya Mallik
-066	Krishnabeni Dash	-066	Krishnabeni Dash
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